

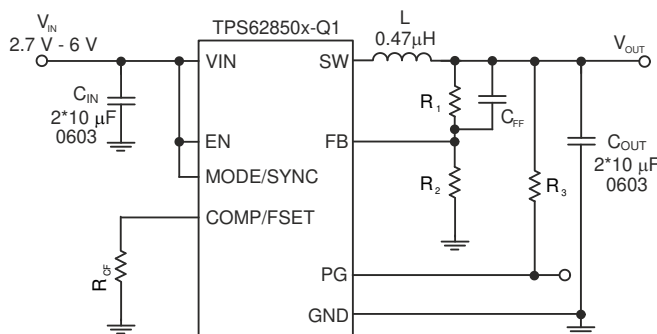
# TPS62850x-Q1 2.7V~6V、1A/2A /3A 車載用降圧コンバータ、SOT583 パッケージ

## 1 特長

- 車載アプリケーション向けに AEC-Q100 認証済み
  - デバイス温度グレード 1:  $-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$  T<sub>A</sub>
- 機能安全対応
  - 機能安全システムの設計に役立つ資料を利用可能
- 低 EMI 要件に対して最適化
  - オプションの疑似ランダム拡散スペクトラムにより、ピーク放射を低減
- T<sub>J</sub> =  $-40^{\circ}\text{C} \sim +150^{\circ}\text{C}$
- 1A、2A (連続)、3A (ピーク) のコンバータ ファミリ
- 入力電圧範囲: 2.7V~6V
- 静止電流: 17μA (代表値)
- 0.6V~5.5V の出力電圧
- 出力電圧精度  $\pm 1\%$  (PWM 動作)
- 強制 PWM または PWM/PFM 動作
- 可変スイッチング周波数: 1.8MHz~4MHz
- 高精度の ENABLE 入力で以下を実現:
  - ユーザー定義の低電圧誤動作防止機能
  - 正確なシーケンシング
- 100% デューティ サイクル モード
- アクティブ出力放電
- フォールドバック過電流保護 – オプション
- ウィンドウ コンパレータによるパワー グッド出力

## 2 アプリケーション

- ADAS カメラ、ADAS センサ・フュージョン
- サラウンド・ビュー ECU
- ハイブリッドおよび再構成可能クラスタ
- ヘッド・ユニット、テレマティクス制御ユニット
- 外部アンプ



概略回路図

## 3 概要

TPS62850x-Q1 はピン互換で 1A、2A (連続) および 3A (ピーク) の高効率で使いやすい同期整流降圧 DC/DC コンバータ ファミリです。これらのデバイスは、ピーク電流モードの制御トポロジに基づいています。これらのデバイスは、インフォテインメント、先進運転支援システムなどの車載アプリケーション用に設計されたものです。低抵抗のスイッチにより、連続で最大 2A、ピークでは 3A の出力電流を供給できます。TPS62850x-Q1 では、スイッチング周波数を 1.8MHz~4MHz の範囲で外部から調整できます。また、上記と同じ周波数範囲で、外部クロックに同期させることも可能です。PWM/PFM モードでは、負荷が軽いときに自動的にパワーセーブ モードへ移行するため、負荷範囲全体にわたって高い効率を維持できます。このファミリは PWM モードで 1% の出力電圧精度を実現しており、出力電圧精度の高い電源の設計に役立ちます。

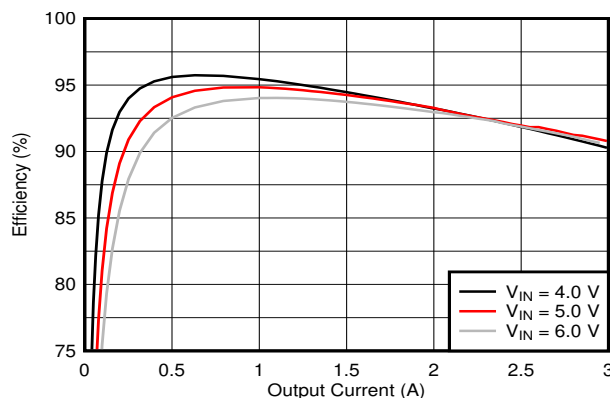
TPS62850x-Q1 は、SOT583 パッケージで供給されます。

### 製品情報

部品番号 <sup>(2)</sup>	パッケージ <sup>(1)</sup>	本体サイズ (公称)
TPS628501-Q1	DRL (SOT583, 8)	2.10mm × 1.60mm (ピンを含む)
TPS628502-Q1		
TPS628503-Q1		
TPS628501-Q1	DYC (SOT583, 8)	2.10mm × 1.60mm (ピンを含む)

(1) 詳細については、[セクション 12](#) を参照してください。

(2) 「製品比較」表を参照してください。


 効率と I<sub>OUT</sub> との関係 (V<sub>OUT</sub> = 3.3V)


## Table of Contents

<b>1 特長</b> .....	1	8.4 Device Functional Modes.....	14
<b>2 アプリケーション</b> .....	1	<b>9 Application and Implementation</b> .....	16
<b>3 概要</b> .....	1	9.1 Application Information.....	16
<b>4 Device Comparison Table</b> .....	3	9.2 Typical Application.....	18
<b>5 Pin Configuration and Functions</b> .....	4	9.3 System Examples.....	28
<b>6 Specifications</b> .....	5	9.4 Power Supply Recommendations.....	29
6.1 Absolute Maximum Ratings.....	5	9.5 Layout.....	29
6.2 ESD Ratings.....	5	<b>10 Device and Documentation Support</b> .....	31
6.3 Recommended Operating Conditions.....	5	10.1 Device Support.....	31
6.4 Thermal Information.....	6	10.2 ドキュメントの更新通知を受け取る方法.....	31
6.5 Electrical Characteristics.....	6	10.3 サポート・リソース.....	31
6.6 Typical Characteristics.....	9	10.4 Trademarks.....	31
<b>7 Parameter Measurement Information</b> .....	10	10.5 静電気放電に関する注意事項.....	31
7.1 Schematic.....	10	10.6 用語集.....	31
<b>8 Detailed Description</b> .....	11	<b>11 Revision History</b> .....	31
8.1 Overview.....	11	<b>12 Mechanical, Packaging, and Orderable Information</b> .....	33
8.2 Functional Block Diagram.....	11		
8.3 Feature Description.....	12		

## 4 Device Comparison Table

DEVICE NUMBER	OUTPUT CURRENT	V <sub>OUT</sub> DISCHARGE	FOLDBACK CURRENT LIMIT	TYPICAL OUTPUT CAPACITOR	SOFT START	OUTPUT VOLTAGE	PACKAGE TYPE
TPS628501QDRLRQ1	1 A	ON	OFF	2 × 10 μF	Internal 1 ms	Adjustable	DRL
TPS6285010MQDYCRQ1	1 A	ON	OFF	2 × 10 μF	Internal 1 ms	Fixed 1.8 V	DYC
TPS62850140QDYCRQ1	1 A	ON	ON	2 × 10 μF	Internal 1 ms	Adjustable	DYC
TPS6285018AQDRLRQ1	1 A	ON	OFF	10 μF	Internal 1 ms	Fixed 1.2 V	DRL
TPS6285011HQDRLRQ1	1 A	ON	OFF	2 × 10 μF	Internal 1 ms	Fixed 3.3 V	DRL
TPS6285010MQDRLRQ1	1 A	ON	OFF	2 × 10 μF	Internal 1 ms	Fixed 1.8 V	DRL
TPS628501B0QDRLRQ1 <sup>(1)</sup>	1 A	ON	OFF	2 × 10 μF	Internal 150 μs	Adjustable	DRL
TPS62850120QDRLRQ1	1 A	OFF	OFF	2 × 10 μF	Internal 1 ms	Adjustable	DRL
TPS628502QDRLRQ1	2 A	ON	OFF	2 × 10 μF	Internal 1 ms	Adjustable	DRL
TPS62850240QDYCRQ1	2 A	ON	ON	2 × 10 μF	Internal 1 ms	Adjustable	DYC
TPS62850220QDRLRQ1	2 A	OFF	OFF	2 × 10 μF	Internal 1 ms	Adjustable	DRL
TPS62850240QDRLRQ1	2 A	ON	ON	2 × 10 μF	Internal 1 ms	Adjustable	DRL
TPS6285020MQDRLRQ1	2 A	ON	OFF	2 × 10 μF	Internal 1 ms	Fixed 1.8 V	DRL
TPS6285021HQDRLRQ1	2 A	ON	OFF	2 × 10 μF	Internal 1 ms	Fixed 3.3 V	DRL
TPS6285020AQDRLRQ1	2 A	ON	OFF	2 × 10 μF	Internal 1 ms	Fixed 1.2 V	DRL
TPS628503QDRLRQ1	3 A	ON	OFF	2 × 10 μF	Internal 1 ms	Adjustable	DRL

(1) Product preview (not Production Data)

## 5 Pin Configuration and Functions

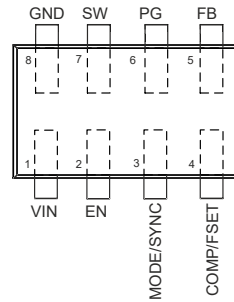
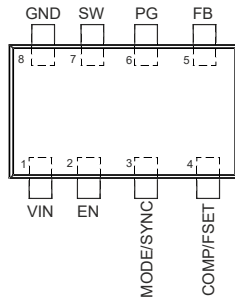


図 5-1. 8-Pin SOT583 DRL Package for TPS62850x-Q1 (Top View)

図 5-2. 8-Pin SOT583 DYC Package for TPS62850x-Q1 (Top View)

表 5-1. Pin Functions

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
EN	2	I	This is the enable pin of the device. Connect to logic low to disable the device. Pull high to enable the device. Do not leave this pin unconnected.
FB	5	I	Voltage feedback input. Connect the resistive output voltage divider to this pin.
GND	8		Ground pin
MODE/SYNC	3	I	The device runs in PFM/PWM mode when this pin is pulled low. When the pin is pulled high, the device runs in forced PWM mode. Do not leave this pin unconnected. The mode pin can also be used to synchronize the device to an external frequency. See <a href="#">セクション 6.5</a> for the detailed specification for the digital signal applied to this pin for external synchronization.
COMP/FSET	4	I	Device compensation and frequency set input. A resistor from this pin to GND defines the compensation of the control loop as well as the switching frequency if not externally synchronized.
PG	6	O	Open-drain power-good output
SW	7		This is the switch pin of the converter and is connected to the internal power MOSFETs.
VIN	1		Power supply input. Make sure the input capacitor is connected as close as possible between the VIN and GND pins.

(1) I = input, O = output

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Pin voltage <sup>(2)</sup>	VIN	-0.3	6.5	V
Pin voltage <sup>(2)</sup>	SW (DC)	-0.3	V <sub>IN</sub> + 0.3	V
Pin voltage <sup>(2)</sup>	SW (AC, less than 10ns) <sup>(3)</sup>	-3	10	V
Pin voltage <sup>(2)</sup>	COMP/FSET, PG	-0.3	V <sub>IN</sub> + 0.3	V
Pin voltage <sup>(2)</sup>	EN, MODE/SYNC, FB	-0.3	6.5	V
T <sub>stg</sub>	Storage temperature	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the network ground terminal
- (3) While switching

### 6.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000	V
		Charged device model (CDM), per AEC Q100-011	±750	

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 6.3 Recommended Operating Conditions

Over operating temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V <sub>IN</sub>	Input voltage range	2.7		6	V
V <sub>OUT</sub>	Output voltage range	0.6		5.5	V
L	Effective inductance	0.32	0.47	1.2	μH
C <sub>OUT</sub>	Effective output capacitance <sup>(1)</sup>	8	10	200	μF
C <sub>IN</sub>	Effective input capacitance <sup>(1)</sup>		10		μF
R <sub>CF</sub>		4.5		100	kΩ
I <sub>SINK_PG</sub>	Sink current at PG pin	0		2	mA
I <sub>OUT</sub>	Output current, TPS628501	0		1	A
I <sub>OUT</sub>	Output current, TPS628502	0		2	A
I <sub>OUT</sub>	Output current, TPS628503 <sup>(2)</sup>	0		3	A
T <sub>J</sub>	Junction temperature	-40		150	°C

- (1) The values given for all the capacitors in the table are effective capacitance, which includes the DC bias effect. Due to the DC bias effect of ceramic capacitors, the effective capacitance is lower than the nominal value when a voltage is applied. Please check the manufacturer's DC bias curves for the effective capacitance vs DC voltage applied. Further restrictions may apply. Please see the feature description for COMP/FSET about the output capacitance vs compensation setting and output voltage.
- (2) This part is designed for a 2-A continuous output current at a junction temperature of 105 °C or 3-A at a junction temperature of 85 °C; exceeding the output current or the junction temperature can significantly reduce lifetime.

## 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS62850x-Q1	TPS62850x-Q1	UNIT
		DRL (JEDEC) <sup>(2)</sup>	DRL (EVM)	
		8 PINS	8 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	110	60	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	41.3	n/a	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	20	n/a	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	0.8	n/a	°C/W
Y <sub>JB</sub>	Junction-to-board characterization parameter	20	n/a	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	n/a	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.  
 (2) JEDEC standard PCB with 4 layers, no thermal vias

## 6.5 Electrical Characteristics

Over operating junction temperature range (T<sub>J</sub> = -40°C to +150°C) and V<sub>IN</sub> = 2.7 V to 6 V. Typical values at V<sub>IN</sub> = 5 V and T<sub>J</sub> = 25°C. (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY</b>						
I <sub>Q</sub>	Quiescent current	EN = V <sub>IN</sub> , no load, device not switching, MODE = GND, V <sub>OUT</sub> = 0.6 V		17	36	μA
I <sub>SD</sub>	Shutdown current	EN = GND, Nominal value at T <sub>J</sub> = 25°C, Max value at T <sub>J</sub> = 150°C		1.5	48	μA
V <sub>UVLO</sub>	Undervoltage lock out threshold	V <sub>IN</sub> rising	2.45	2.6	2.7	V
		V <sub>IN</sub> falling	2.1	2.5	2.6	V
T <sub>JSD</sub>	Thermal shutdown threshold	T <sub>J</sub> rising		170		°C
	Thermal shutdown hysteresis	T <sub>J</sub> falling		15		°C
<b>CONTROL and INTERFACE</b>						
V <sub>EN,IH</sub>	Input threshold voltage at EN, rising edge		1.05	1.1	1.15	V
V <sub>EN,IL</sub>	Input threshold voltage at EN, falling edge		0.96	1.0	1.05	V
V <sub>IH</sub>	High-level input-threshold voltage at MODE/SYNC		1.1			V
I <sub>EN,LKG</sub>	Input leakage current into EN	V <sub>IH</sub> = V <sub>IN</sub> or V <sub>IL</sub> = GND			125	nA
V <sub>IL</sub>	Low-level input-threshold voltage at MODE/SYNC				0.3	V
I <sub>LKG</sub>	Input leakage current into MODE/SYNC				100	nA
t <sub>Delay</sub>	Enable delay time	Time from EN high to device starts switching; V <sub>IN</sub> applied already	135	200	520	μs
t <sub>Delay</sub>	Enable delay time	Time from EN high to device starts switching; V <sub>IN</sub> applied already, V <sub>IN</sub> ≥ 3.3 V			480	μs
t <sub>Ramp</sub>	Output voltage ramp time	Time from device starts switching to power good; device not in current limit	0.8	1.3	1.8	ms
t <sub>Ramp</sub>	Output voltage ramp time	Time from device starts switching to power good; device not in current limit	90	150	210	μs
f <sub>SYNC</sub>	Frequency range on MODE/SYNC pin for synchronization		1.8		4	MHz
	Duty cycle of synchronization signal at MODE/SYNC		20		80	%
	Time to lock to external frequency			50		μs

## 6.5 Electrical Characteristics (続き)

Over operating junction temperature range ( $T_J = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ) and  $V_{IN} = 2.7\text{ V}$  to  $6\text{ V}$ . Typical values at  $V_{IN} = 5\text{ V}$  and  $T_J = 25^\circ\text{C}$ . (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	resistance from COMP/FSET to GND for logic low	internal frequency setting with $f = 2.25\text{ MHz}$	0		2.5	k $\Omega$
	Voltage on COMP/FSET for logic high	internal frequency setting with $f = 2.25\text{ MHz}$		$V_{IN}$		V
$V_{TH\_PG}$	UVP power good threshold voltage; DC level	rising ( $\%V_{FB}$ )	92	95	98	%
$V_{TH\_PG}$	UVP power good threshold voltage; DC level	falling ( $\%V_{FB}$ )	87	90	93	%
$V_{TH\_PG}$	OVP power good threshold voltage; DC level	rising ( $\%V_{FB}$ )	107	110	113	%
	OVP power good threshold voltage; DC level	falling ( $\%V_{FB}$ )	104	107	111	%
$V_{PG\_OL}$	Low-level output voltage at PG	$I_{SINK\_PG} = 2\text{ mA}$		0.07	0.3	V
$I_{PG\_LKG}$	Input leakage current into PG	$V_{PG} = 5\text{ V}$			100	nA
$t_{PG}$	PG deglitch time	for a high level to low level transition on the power good output		40		$\mu\text{s}$
<b>OUTPUT</b>						
$V_{FB}$	Feedback voltage, adjustable version			0.6		V
$V_{FB}$	Feedback voltage, fixed voltage versions	for TPS62850108		1.1		V
$V_{FB}$	Feedback voltage, fixed voltage versions	for TPS6285018A		1.2		V
$V_{FB}$	Feedback voltage, fixed voltage versions	for TPS6285010M, TPS6285020M		1.8		V
$V_{FB}$	Feedback voltage, fixed voltage versions	for TPS6285021H		3.3		V
$I_{FB\_LKG}$	Input leakage current into FB, adjustable version	$V_{FB} = 0.6\text{ V}$		1	70	nA
$I_{FB\_LKG}$	Input leakage current into FB, fixed voltage versions			1		nA
$V_{FB}$	Feedback voltage accuracy	PWM, $V_{IN} \geq V_{OUT} + 1\text{ V}$	-1		1	%
$V_{FB}$	Feedback voltage accuracy	PFM, $V_{IN} \geq V_{OUT} + 1\text{ V}$ , $V_{OUT} \geq 1.0\text{ V}$ , $C_{o,eff} \geq 10\text{ }\mu\text{F}$ , $L = 0.47\text{ }\mu\text{H}$	-1		2	%
$V_{FB}$	Feedback voltage accuracy	PFM, $V_{IN} \geq V_{OUT} + 1\text{ V}$ , $V_{OUT} < 1.0\text{ V}$ , $C_{o,eff} \geq 15\text{ }\mu\text{F}$ , $L = 0.47\text{ }\mu\text{H}$	-1		3	%
	Load regulation	PWM		0.05		%/A
	Line regulation	PWM, $I_{OUT} = 1\text{ A}$ , $V_{IN} \geq V_{OUT} + 1\text{ V}$		0.02		%/V
$R_{DIS}$	Output discharge resistance				100	$\Omega$
$f_{SW}$	PWM Switching frequency range	MODE = high, see the FSET pin functionality about setting the switching frequency	1.8	2.25	4	MHz
$f_{SW}$	PWM Switching frequency range	MODE = low, see the FSET pin functionality about setting the switching frequency	1.8		3.5	MHz
$f_{SW}$	PWM Switching frequency	with COMP/FSET tied to GND or $V_{IN}$	2.025	2.25	2.475	MHz
$f_{SW}$	PWM Switching frequency tolerance	using a resistor from COMP/FSET to GND	-12		12	%
$t_{on,min}$	Minimum on-time of high-side FET	$V_{IN} \geq 3.3\text{ V}$ , $T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$		35	50	ns
$t_{on,min}$	Minimum on-time of low-side FET			10		ns

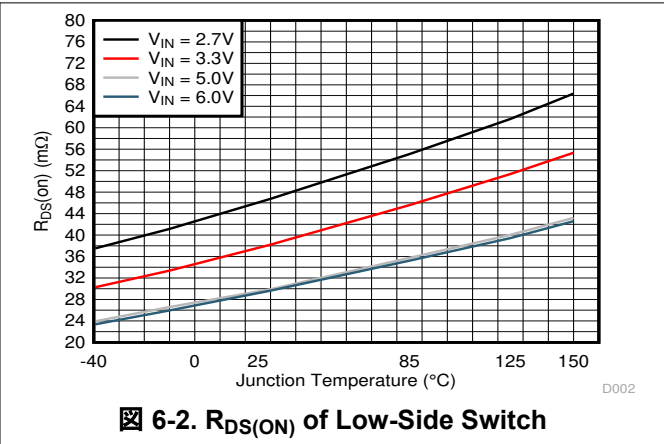
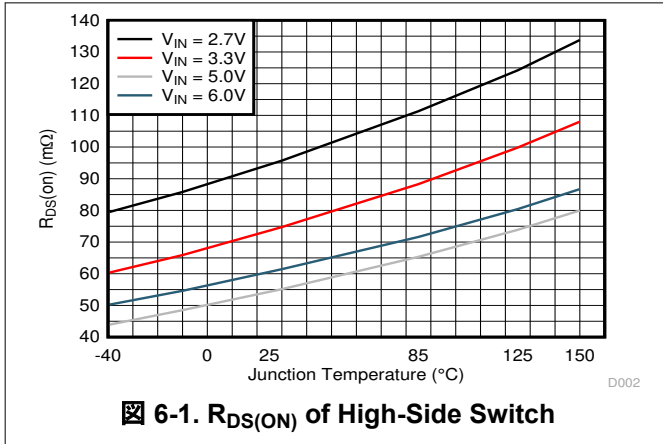
## 6.5 Electrical Characteristics (続き)

Over operating junction temperature range ( $T_J = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ) and  $V_{IN} = 2.7\text{ V}$  to  $6\text{ V}$ . Typical values at  $V_{IN} = 5\text{ V}$  and  $T_J = 25^\circ\text{C}$ . (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{DS(ON)}$	High-side FET on-resistance	$V_{IN} \geq 5\text{ V}$		65	120	m $\Omega$
	Low-side FET on-resistance	$V_{IN} \geq 5\text{ V}$		33	70	m $\Omega$
	High-side MOSFET leakage current	$T_J = 85^\circ\text{C}$		2.5		$\mu\text{A}$
	High-side MOSFET leakage current			0.01	44	$\mu\text{A}$
	Low-side MOSFET leakage current	$T_J = 85^\circ\text{C}$		3.7		$\mu\text{A}$
	Low-side MOSFET leakage current			0.01	70	$\mu\text{A}$
	SW leakage	$V(\text{SW}) = 0.6\text{V}$ , current into SW pin	-0.05		11	$\mu\text{A}$
$I_{LIMH}$	High-side FET switch current limit	DC value, for TPS628503; $V_{IN} = 3.3\text{ V}$ to $6\text{ V}$	3.45	4.5	5.1	A
$I_{LIMH}$	High-side FET switch current limit	DC value, for TPS628502; $V_{IN} = 3\text{ V}$ to $6\text{ V}$	2.85	3.4	3.9	A
$I_{LIMH}$	High-side FET switch current limit	DC value, for TPS628501; $V_{IN} = 3\text{ V}$ to $6\text{ V}$	2.1	2.6	3.0	A
$I_{LIMNEG}$	Low-side FET negative current limit	DC value		-1.8		A



## 6.6 Typical Characteristics



## 7 Parameter Measurement Information

### 7.1 Schematic

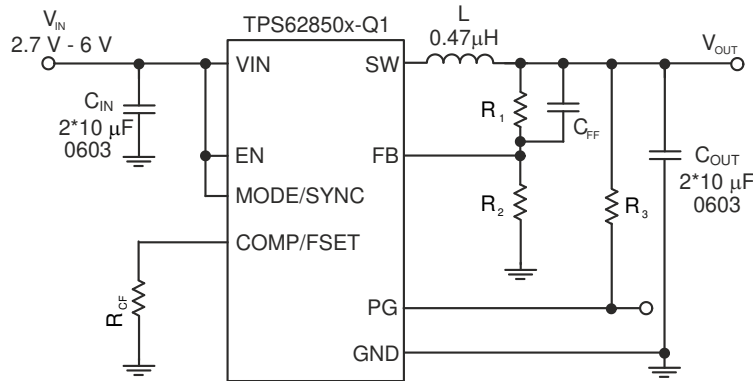


図 7-1. Measurement Setup (TPS62850x-Q1)

表 7-1. List of Components

REFERENCE	DESCRIPTION	MANUFACTURER <sup>(1)</sup>
IC	TPS628502QDRLRQ1	Texas Instruments
L	0.47- $\mu$ H inductor DFE252012PD	Murata
C <sub>IN</sub>	2 $\times$ 10 $\mu$ F / 6.3 V GCM188D70J106M	Murata
C <sub>OUT</sub>	2 $\times$ 10 $\mu$ F / 6.3 V GCM188D70J106M for V <sub>out</sub> $\geq$ 1 V	Murata
C <sub>OUT</sub>	3 $\times$ 10 $\mu$ F / 6.3 V GCM188D70J106M for V <sub>out</sub> < 1 V	Murata
R <sub>CF</sub>	8,06 k $\Omega$	Any
C <sub>FF</sub>	10 pF	Any
R <sub>1</sub>	Depending on V <sub>OUT</sub>	Any
R <sub>2</sub>	Depending on V <sub>OUT</sub>	Any
R <sub>3</sub>	100 k $\Omega$	Any

(1) See the [Third-party Products Disclaimer](#).

## 8 Detailed Description

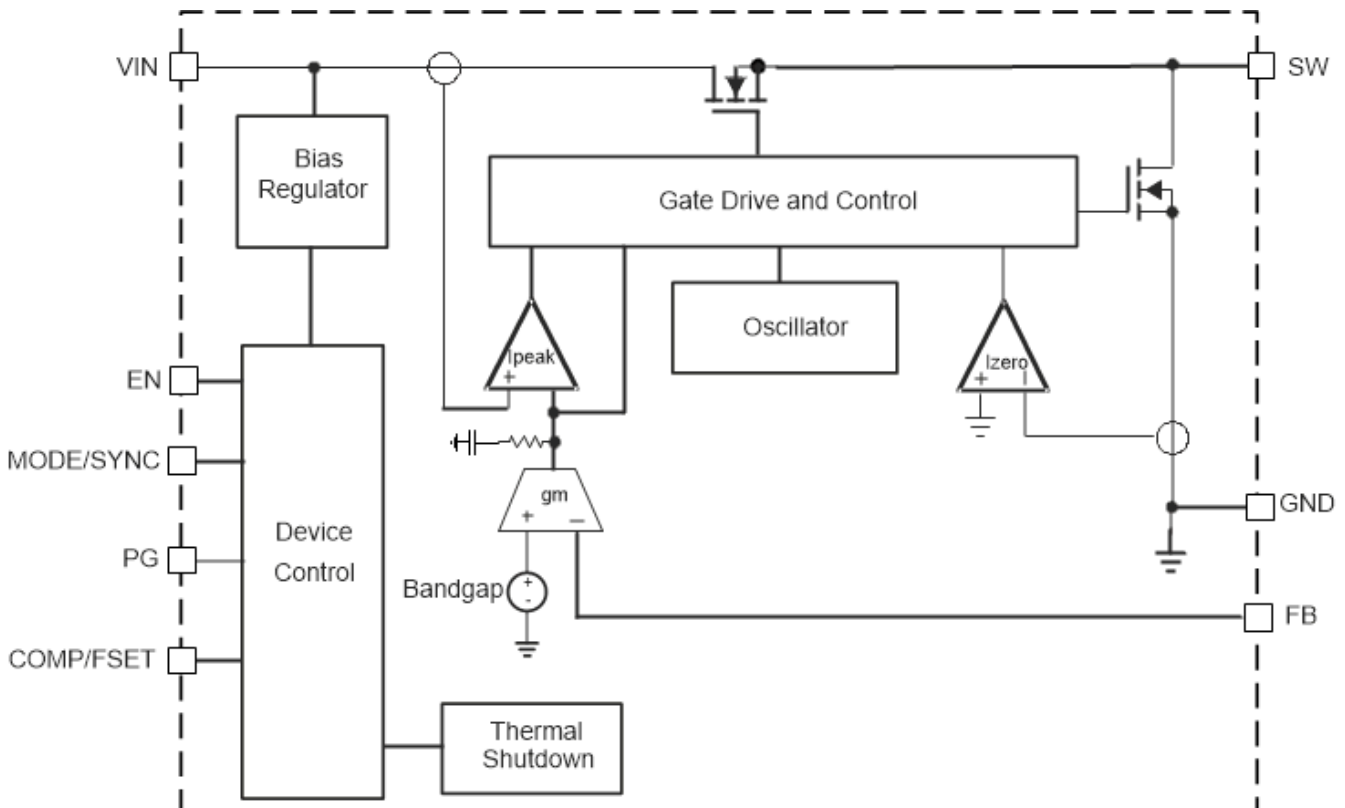
### 8.1 Overview

The TPS62850x-Q1 synchronous switch mode power converters are based on a peak current mode control topology. The control loop is internally compensated.

To optimize the bandwidth of the control loop to the wide range of output capacitance that can be used with the TPS62850x-Q1, the internal compensation has two settings. See [セクション 8.3.2](#). One out of the two compensation settings is chosen either by a resistor from COMP/FSET to GND, or by the logic state of this pin. The regulation network achieves fast and stable operation with small external components and low-ESR ceramic output capacitors. The devices can be operated without a feedforward capacitor on the output voltage divider, however, using a typically 10-pF feedforward capacitor improves transient response.

The devices support forced fixed frequency PWM operation with the MODE pin tied to a logic high level. The frequency is defined as either 2.25 MHz internally fixed for the TPS62850x-Q1 when COMP/FSET is tied to GND or VIN, or in a range of 1.8 MHz to 4 MHz defined by a resistor from COMP/FSET to GND. Alternatively, the devices can be synchronized to an external clock signal in a range from 1.8 MHz to 4 MHz, applied to the MODE pin with no need for additional passive components. An internal PLL allows you to change from internal clock to external clock during operation. The synchronization to the external clock is done on a falling edge of the clock applied at MODE to the rising edge on the SW pin. This allows a roughly 180° phase shift when the SW pin is used to generate the synchronization signal for a second converter. When the MODE pin is set to a logic low level, the device operates in power save mode (PFM) at low output current and automatically transfers to fixed frequency PWM mode at higher output current. In PFM mode, the switching frequency decreases linearly based on the load to sustain high efficiency down to very low output current.

### 8.2 Functional Block Diagram



## 8.3 Feature Description

### 8.3.1 Precise Enable (EN)

The voltage applied at the enable pin of the TPS62850x-Q1 is compared to a fixed threshold of 1.1 V for a rising voltage. This allows you to drive the pin by a slowly changing voltage and enables the use of an external RC network to achieve a power-up delay.

The Precise Enable input provides a user-programmable undervoltage lockout by adding a resistor divider to the input of the Enable pin.

The enable input threshold for a falling edge is typically 100 mV lower than the rising edge threshold. The TPS62850x-Q1 starts operation when the rising threshold is exceeded. For proper operation, the enable (EN) pin must be terminated and must not be left floating. Pulling the enable pin low forces the device into shutdown, with a shutdown current of typically 1  $\mu$ A. In this mode, the internal high-side and low-side MOSFETs are turned off and the entire internal control circuitry is switched off.

### 8.3.2 COMP/FSET

This pin allows to set three different parameters:

- Internal compensation settings for the control loop (two settings available)
- The switching frequency in PWM mode from 1.8 MHz to 4 MHz
- Enable/disable spread spectrum clocking (SSC)

A resistor from COMP/FSET to GND changes the compensation as well as the switching frequency. The change in compensation allows you to adopt the device to different values of output capacitance. The resistor must be placed close to the pin to keep the parasitic capacitance on the pin to a minimum. The compensation setting is sampled at start up of the converter, so a change in the resistor during operation only has an effect on the switching frequency but not on the compensation.

To save external components, the pin can also be directly tied to VIN or GND to set a pre-defined setting. Do not leave the pin floating.

The switching frequency has to be selected based on the input voltage and the output voltage to meet the specifications for the minimum on-time and minimum off-time.

Example:  $V_{IN} = 5\text{ V}$ ,  $V_{OUT} = 0.6\text{ V}$  --> duty cycle =  $0.6\text{ V} / 5\text{ V} = 0.12$

- -->  $t_{on,min} = 1 / f_s \times 0.12$
- -->  $f_{sw,max} = 1 / t_{on,min} \times 0.12 = 1 / 0.05\ \mu\text{s} \times 0.12 = 2.4\text{ MHz}$

The compensation range has to be chosen based on the minimum capacitance used. The capacitance can be increased from the minimum value as given in 表 8-1, up to the maximum of 200  $\mu$ F in both compensation ranges. If the capacitance of an output changes during operation, for example, when load switches are used to connect or disconnect parts of the circuitry, the compensation has to be chosen for the minimum capacitance on the output. With large output capacitance, the compensation must be done based on that large capacitance to get the best load transient response. Compensating for large output capacitance but placing less capacitance on the output can lead to instability.

The switching frequency for the different compensation setting is determined by the following equations.

For compensation (comp) setting 1 with spread spectrum clocking (SSC) disabled:

$$R_{CF}(k\Omega) = \frac{18\text{MHz} \cdot k\Omega}{f_s(\text{MHz})} \quad (1)$$

For compensation (comp) setting 1 with spread spectrum clocking (SSC) enabled:

$$R_{CF}(k\Omega) = \frac{60MHz \cdot k\Omega}{f_s(MHz)} \quad (2)$$

For compensation (comp) setting 2 with spread spectrum clocking (SSC) disabled:

$$R_{CF}(k\Omega) = \frac{180MHz \cdot k\Omega}{f_s(MHz)} \quad (3)$$

**表 8-1. Switching Frequency, Compensation, and Spread Spectrum Clocking**

$R_{CF}$	COMPENSATION	SWITCHING FREQUENCY	MINIMUM OUTPUT CAPACITANCE FOR $V_{OUT} < 1 V$	MINIMUM OUTPUT CAPACITANCE FOR $1 V \leq V_{OUT} < 3.3 V$	MINIMUM OUTPUT CAPACITANCE FOR $V_{OUT} \geq 3.3 V$
10 k $\Omega$ .. 4.5 k $\Omega$	for smallest output capacitance (comp setting 1) SSC disabled	1.8 MHz (10 k $\Omega$ ) .. 4 MHz (4.5 k $\Omega$ ) according to <a href="#">式 1</a>	15 $\mu F$	10 $\mu F$	8 $\mu F$
33 k $\Omega$ .. 15 k $\Omega$	for best transient response (larger output capacitance) (comp setting 2) SSC enabled	1.8 MHz (33 k $\Omega$ ) .. 4 MHz (15 k $\Omega$ ) according to <a href="#">式 2</a>	30 $\mu F$	18 $\mu F$	15 $\mu F$
100 k $\Omega$ .. 45 k $\Omega$	for best transient response (larger output capacitance) (comp setting 2) SSC disabled	1.8 MHz (100 k $\Omega$ ) .. 4 MHz (45 k $\Omega$ ) according to <a href="#">式 3</a>	30 $\mu F$	18 $\mu F$	15 $\mu F$
tied to GND	for smallest output capacitance (comp setting 1) SSC disabled	internally fixed 2.25 MHz	15 $\mu F$	10 $\mu F$	8 $\mu F$
tied to $V_{IN}$	for best transient response (larger output capacitance) (comp setting 2) SSC enabled	internally fixed 2.25 MHz	30 $\mu F$	18 $\mu F$	15 $\mu F$

Refer to [セクション 9.1.3.2](#) for further details on the output capacitance required depending on the output voltage.

A resistor value that is too high for  $R_{CF}$  is decoded as "tied to  $V_{IN}$ ", a value below the lowest range is decoded as "tied to GND". The minimum output capacitance in [表 8-1](#) is for capacitors close to the output of the device. If the capacitance is distributed, a lower compensation setting can be required.

### 8.3.3 MODE / SYNC

When MODE/SYNC is set low, the device operates in PWM or PFM mode, depending on the output current. The MODE/SYNC pin allows you to force PWM mode when set high. The pin also allows you to apply an external clock in a frequency range from 1.8 MHz to 4 MHz for external synchronization. The specifications for the minimum on-time and minimum off-time has to be observed when setting the external frequency. For use with external synchronization on the MODE/SYNC pin, the internal switching frequency must be set by  $R_{CF}$  to a similar value than the externally applied clock. This ensures that, if the external clock fails, the switching frequency stays in the same range and the compensation settings are still valid.

### 8.3.4 Spread Spectrum Clocking (SSC)

The device offers spread spectrum clocking as an option. When SSC is enabled, the switching frequency is randomly changed in PWM mode when the internal clock is used. The frequency variation is typically between the nominal switching frequency and up to 288 kHz above the nominal switching frequency. When the device is externally synchronized by applying a clock signal to the MODE/SYNC pin, the TPS62850x-Q1 follows the external clock and the internal spread spectrum block is turned off. SSC is also disabled during soft start.

### 8.3.5 Undervoltage Lockout (UVLO)

If the input voltage drops, the undervoltage lockout prevents misoperation of the device by switching off both the power FETs. When enabled, the device is fully operational for input voltages above the rising UVLO threshold and turns off if the input voltage trips below the threshold for a falling supply voltage.

### 8.3.6 Power-Good Output (PG)

Power good is an open-drain output that requires a pullup resistor to any voltage up to the recommended input voltage level. Power good is driven by a window comparator. PG is held low when the device is disabled, in undervoltage lockout in thermal shutdown, and not in soft start. When the output voltage is in regulation hence, within the window defined in the electrical characteristics, the output is high impedance.

$V_{IN}$  must remain present for the PG pin to stay low. If the power good output is not used, TI recommends to tie to GND or leave open. The PG indicator features a de-glitch, as specified in the electrical characteristics, for the transition from "high impedance" to "low" of its output.

表 8-2. PG Status

EN	DEVICE STATUS	PG STATE
X	$V_{IN} < 2\text{ V}$	undefined
low	$V_{IN} \geq 2\text{ V}$	low
high	$2\text{ V} \leq V_{IN} \leq \text{UVLO}$ OR in thermal shutdown OR $V_{OUT}$ not in regulation OR device in soft start	low
high	$V_{OUT}$ in regulation	high impedance

### 8.3.7 Thermal Shutdown

The junction temperature ( $T_J$ ) of the device is monitored by an internal temperature sensor. If  $T_J$  exceeds 170°C (typ), the device goes into thermal shutdown. Both the high-side and low-side power FETs are turned off and PG goes low. When  $T_J$  decreases below the hysteresis amount of typically 15°C, the converter resumes normal operation, beginning with soft start. During a PFM pause, the thermal shutdown is not active. After a PFM pause, the device needs up to 9  $\mu\text{s}$  to detect a junction temperature that is too high. If the PFM burst is shorter than this delay, the device does not detect a junction temperature that is too high.

## 8.4 Device Functional Modes

### 8.4.1 Pulse Width Modulation (PWM) Operation

The TPS62850x-Q1 has two operating modes: forced PWM mode, which is discussed in this section, and PWM/PFM as discussed in [セクション 8.4.2](#).

With the MODE/SYNC pin set to high, the TPS62850x-Q1 operates with pulse width modulation in continuous conduction mode (CCM). The switching frequency is defined by a resistor from the COMP pin to GND or by an external clock signal applied to the MODE/SYNC pin. With an external clock applied to MODE/SYNC, the TPS62850x-Q1 follow the frequency applied to the pin. In general, the frequency range in forced PWM mode is 1.8 MHz to 4 MHz. However, the frequency must be in a range the TPS62850x-Q1 can operate at, taking the minimum on-time into account.

### 8.4.2 Power Save Mode Operation (PWM/PFM)

When the MODE/SYNC pin is low, power save mode is allowed. The device operates in PWM mode as long as the peak inductor current is above the PFM threshold of about 0.8 A. When the peak inductor current drops below the PFM threshold, the device starts to skip switching pulses. In power save mode, the switching frequency decreases with the load current maintaining high efficiency. In addition, the frequency set with the resistor on COMP/FSET must be in a range of 1.8 MHz to 3.5 MHz.

### 8.4.3 100% Duty-Cycle Operation

The duty cycle of a buck converter operated in PWM mode is given as  $D = V_{OUT} / V_{IN}$ . The duty cycle increases as the input voltage comes close to the output voltage and the off-time gets smaller. When the

minimum off-time of typically 10 ns is reached, the TPS62850x-Q1 skips switching cycles while it approaches 100% mode. In 100% mode, it keeps the high-side switch on continuously. The high-side switch stays turned on as long as the output voltage is below the target. In 100% mode, the low-side switch is turned off. The maximum dropout voltage in 100% mode is the product of the on-resistance of the high-side switch plus the series resistance of the inductor and the load current.

#### 8.4.4 Current Limit and Short Circuit Protection

The TPS62850x-Q1 is protected against overload and short circuit events. If the inductor current exceeds the current limit  $I_{LIMH}$ , the high-side switch is turned off and the low-side switch is turned on to ramp down the inductor current. The high-side switch turns on again only if the current in the low side-switch has decreased below the low side current limit. Due to internal propagation delay, the actual current can exceed the static current limit. The dynamic current limit is given as:

$$I_{peak(typ)} = I_{LIMH} + \frac{V_L}{L} \cdot t_{PD} \quad (4)$$

where

- $I_{LIMH}$  is the static current limit as specified in the electrical characteristics
- $L$  is the effective inductance at the peak current
- $V_L$  is the voltage across the inductor ( $V_{IN} - V_{OUT}$ )
- $t_{PD}$  is the internal propagation delay of typically 50 ns

The current limit can exceed static values, especially if the input voltage is high and very small inductances are used. The dynamic high-side switch peak current can be calculated as follows:

$$I_{peak(typ)} = I_{LIMH} + \frac{V_{IN} - V_{OUT}}{L} \cdot 50ns \quad (5)$$

#### 8.4.5 Foldback Current Limit and Short-Circuit Protection

This is valid for devices where foldback current limit is enabled. If interested in this option, please contact Texas Instruments.

When the device detects current limit for more than 1024 subsequent switching cycles, it reduces the current limit from its nominal value to typically 1.3 A. Foldback current limit is left when the current limit indication goes away. If device operation continues in current limit, it can, after 3072 switching cycles, try for full current limit again for 1024 switching cycles.

#### 8.4.6 Output Discharge

The purpose of the discharge function is to ensure a defined down-ramp of the output voltage when the device is being disabled and to keep the output voltage close to 0 V when the device is off. The output discharge feature is only active after the TPS62850x-Q1 have been enabled at least once since the supply voltage was applied. The discharge function is enabled as soon as the device is disabled, in thermal shutdown, or in undervoltage lockout. The minimum supply voltage required for the discharge function to remain active typically is 2 V. Output discharge is not activated during a current limit or foldback current limit event.

#### 8.4.7 Input Overvoltage Protection

When the input voltage exceeds the absolute maximum rating, the device is set to PFM mode so it cannot transfer energy from the output to the input.

## 9 Application and Implementation

### 注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくこととなります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

### 9.1 Application Information

#### 9.1.1 Programming the Output Voltage

The output voltage of the TPS62850x-Q1 is adjustable. The output voltage can be programmed for output voltages from 0.6 V to 5.5 V using a resistor divider from V<sub>OUT</sub> to GND. The voltage at the FB pin is regulated to 600 mV. The value of the output voltage is set by the selection of the resistor divider from 式 6. TI recommends to choose resistor values that allow a current of at least 2 μA, meaning the value of R<sub>2</sub> must not exceed 400 kΩ. TI recommends lower resistor values for highest accuracy and most robust design.

$$R_1 = R_2 \cdot \left( \frac{V_{OUT}}{V_{FB}} - 1 \right) \quad (6)$$

#### 9.1.2 External Component Selection

##### 9.1.2.1 Inductor Selection

The TPS62850x-Q1 is designed for a nominal 0.47-μH inductor with a switching frequency of typically 2.25 MHz. Larger values can be used to achieve a lower inductor current ripple but they can have a negative impact on efficiency and transient response. Smaller values than 0.47 μH cause a larger inductor current ripple which causes larger negative inductor current in forced PWM mode at low or no output current. For a higher or lower nominal switching frequency, the inductance must be changed accordingly. See セクション 6.3 for details.

The inductor selection is affected by several effects like inductor ripple current, output ripple voltage, PWM-to-PFM transition point, and efficiency. In addition, the inductor selected has to be rated for appropriate saturation current and DC resistance (DCR). 式 7 calculates the maximum inductor current.

$$I_{L(max)} = I_{OUT(max)} + \frac{\Delta I_{L(max)}}{2} \quad (7)$$

$$\Delta I_{L(max)} = \frac{V_{OUT} \cdot \left( 1 - \frac{V_{OUT}}{V_{IN}} \right)}{L \min} \cdot \frac{1}{f_{SW}} \quad (8)$$

where

- I<sub>L(max)</sub> is the maximum inductor current
- ΔI<sub>L(max)</sub> is the peak-to-peak inductor ripple current
- L<sub>min</sub> is the minimum inductance at the operating point

表 9-1. Typical Inductors

TYPE	INDUCTANCE	CURRENT (1)	FOR DEVICE	NOMINAL SWITCHING FREQUENCY	DIMENSIONS [LxWxH] mm	MANUFACTURER(2)
XFL4015-471ME	0.47 μH, ±20%	3.5 A	TPS628501 / 502	2.25 MHz	4 × 4 × 1.6	Coilcraft
XFL4015-701ME	0.70 μH, ±20%	3.3 A	TPS628501 / 502	2.25 MHz	4 × 4 × 1.6	Coilcraft
XEL3520-801ME	0.80 μH, ±20%	2.0 A	TPS628501 / 502	2.25 MHz	3.5 × 3.2 × 2.0	Coilcraft
XEL3515-561ME	0.56 μH, ±20%	4.5 A	TPS628501 / 502	2.25 MHz	3.5 × 3.2 × 1.5	Coilcraft



**表 9-1. Typical Inductors (続き)**

TYPE	INDUCTANCE	CURRENT <sup>(1)</sup>	FOR DEVICE	NOMINAL SWITCHING FREQUENCY	DIMENSIONS [LxWxH] mm	MANUFACTURER <sup>(2)</sup>
XFL3012-681ME	0.68 $\mu$ H, $\pm$ 20%	2.1 A	TPS628501 / 502	2.25 MHz	3.0 $\times$ 3.0 $\times$ 1.2	Coilcraft
XPL2010-681ML	0.68 $\mu$ H, $\pm$ 20%	1.5 A	TPS628501	2.25 MHz	2 $\times$ 1.9 $\times$ 1	Coilcraft
DFE252012PD-R68M	0.68 $\mu$ H, $\pm$ 20%	see data sheet	TPS628501 / 502	2.25 MHz	2.5 $\times$ 2 $\times$ 1.2	Murata
DFE252012PD-R47M	0.47 $\mu$ H, $\pm$ 20%	see data sheet	TPS628501 / 502	2.25 MHz	2.5 $\times$ 2 $\times$ 1.2	Murata
DFE201612PD-R68M	0.68 $\mu$ H, $\pm$ 20%	see data sheet	TPS628501 / 502	2.25 MHz	2 $\times$ 1.6 $\times$ 1.2	Murata
DFE201612PD-R47M	0.47 $\mu$ H, $\pm$ 20%	see data sheet	TPS628501 / 502	2.25 MHz	2 $\times$ 1.6 $\times$ 1.2	Murata

(1) Lower of  $I_{RMS}$  at 20°C rise or  $I_{SAT}$  at 20% drop.

(2) See the [Third-party Products Disclaimer](#).

Calculating the maximum inductor current using the actual operating conditions gives the minimum saturation current of the inductor needed. TI recommends a margin of about 20% to add. A larger inductor value is also useful to get lower ripple current, but increases the transient response time and size as well.

### 9.1.3 Capacitor Selection

#### 9.1.3.1 Input Capacitor

For most applications, 10- $\mu$ F nominal is sufficient and recommended. The input capacitor buffers the input voltage for transient events and also decouples the converter from the supply. TI recommends a low-ESR multilayer ceramic capacitor (MLCC) for best filtering and must be placed between VIN and GND as close as possible to those pins.

#### 9.1.3.2 Output Capacitor

The architecture of the TPS62850x-Q1 allows the use of tiny ceramic output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get narrow capacitance variation with temperature, TI recommends to use X7R or X5R dielectric. Using a higher value has advantages like smaller voltage ripple and a tighter DC output accuracy in power save mode.

The COMP/FSET pin allows you to select two different compensation settings based on the minimum capacitance used on the output. The maximum capacitance is 200  $\mu$ F in any of the compensation settings. The minimum capacitance required on the output depends on the compensation setting and output voltage.

For output voltages below 1 V, the minimum increases linearly from 10  $\mu$ F at 1 V to 15  $\mu$ F at 0.6 V with the compensation setting for smallest output capacitance. Other compensation ranges are equivalent. See [表 8-1](#) for details.

## 9.2 Typical Application

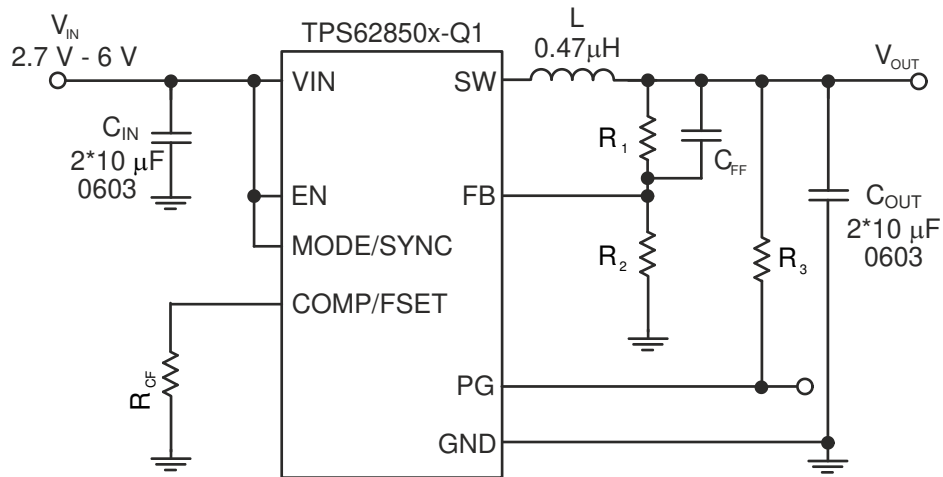


図 9-1. Typical Application

### 9.2.1 Design Requirements

The design guidelines provide a component selection to operate the device within the recommended operating conditions.

### 9.2.2 Detailed Design Procedure

$$R_1 = R_2 \cdot \left( \frac{V_{OUT}}{V_{FB}} - 1 \right) \quad (9)$$

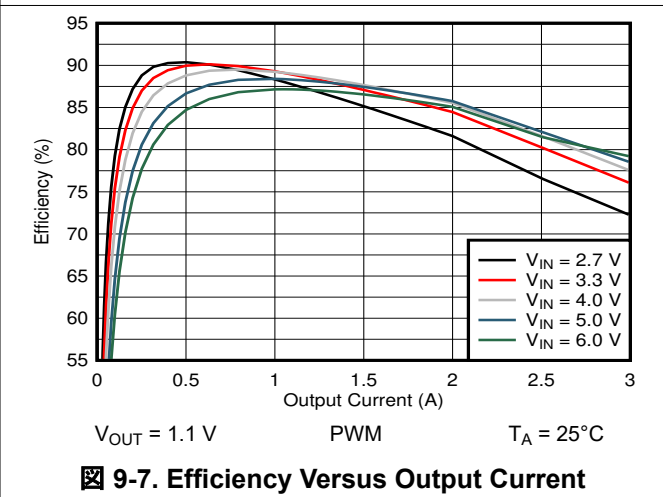
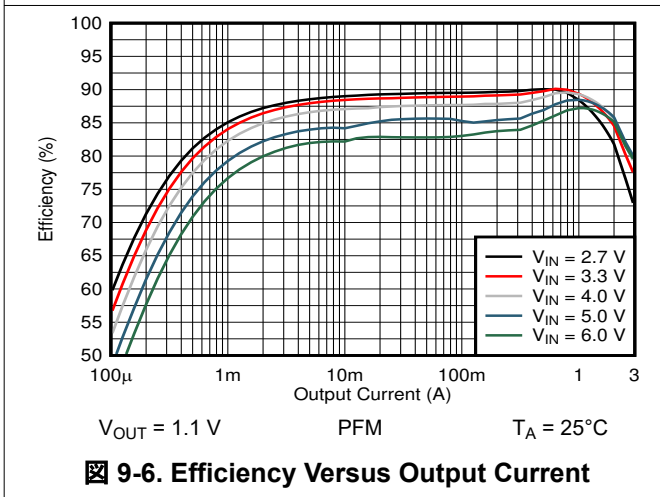
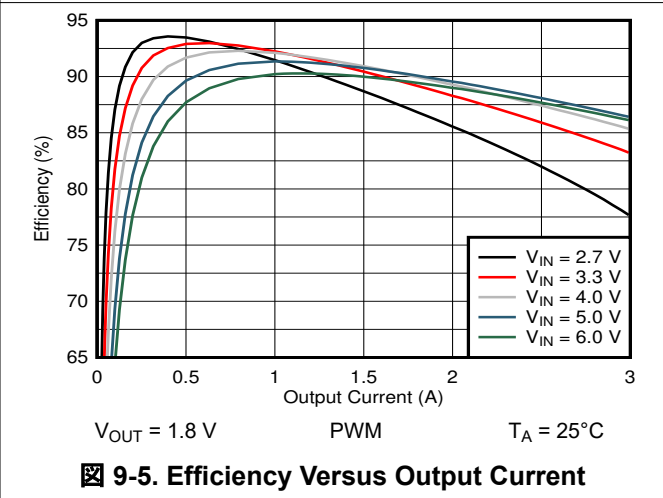
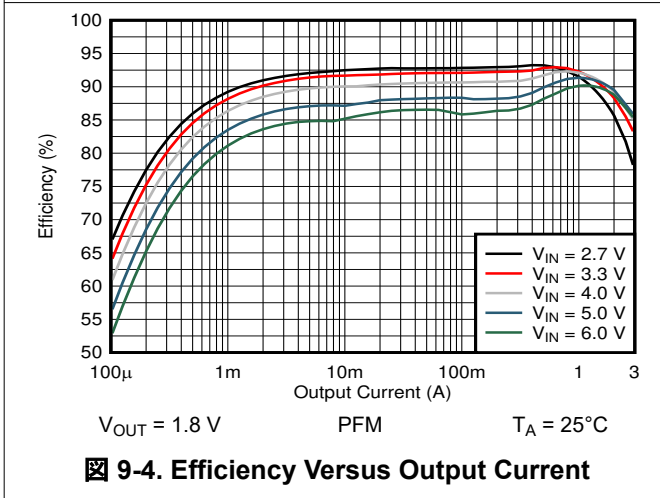
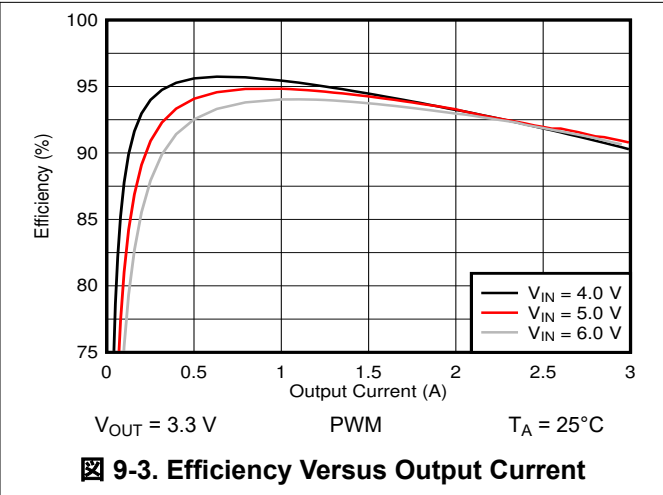
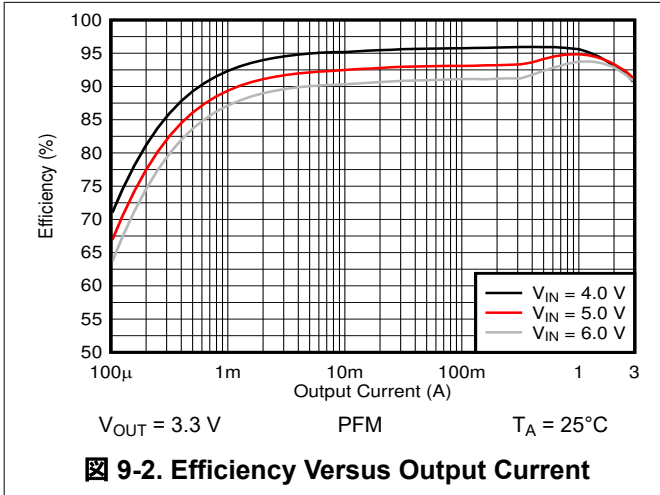
With  $V_{FB} = 0.6 \text{ V}$ :

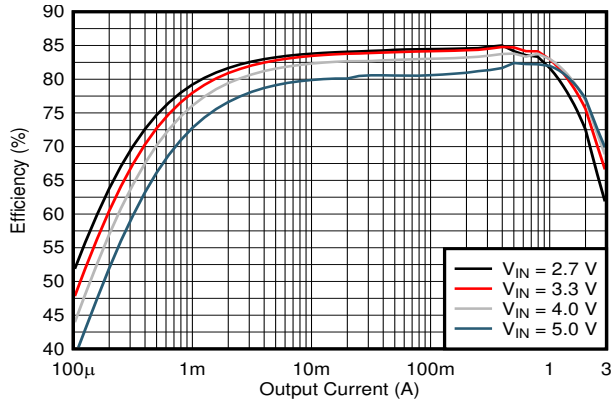
表 9-2. Setting the Output Voltage

NOMINAL OUTPUT VOLTAGE $V_{OUT}$	$R_1$	$R_2$	$C_{FF}$	EXACT OUTPUT VOLTAGE
0.8 V	16.9 k $\Omega$	51 k $\Omega$	10 pF	0.7988 V
1.0 V	20 k $\Omega$	30 k $\Omega$	10 pF	1.0 V
1.1 V	39.2 k $\Omega$	47 k $\Omega$	10 pF	1.101 V
1.2 V	68 k $\Omega$	68 k $\Omega$	10 pF	1.2 V
1.5 V	76.8 k $\Omega$	51 k $\Omega$	10 pF	1.5 V
1.8 V	80.6 k $\Omega$	40.2 k $\Omega$	10 pF	1.803 V
2.5 V	47.5 k $\Omega$	15 k $\Omega$	10 pF	2.5 V
3.3 V	88.7 k $\Omega$	19.6 k $\Omega$	10 pF	3.315 V

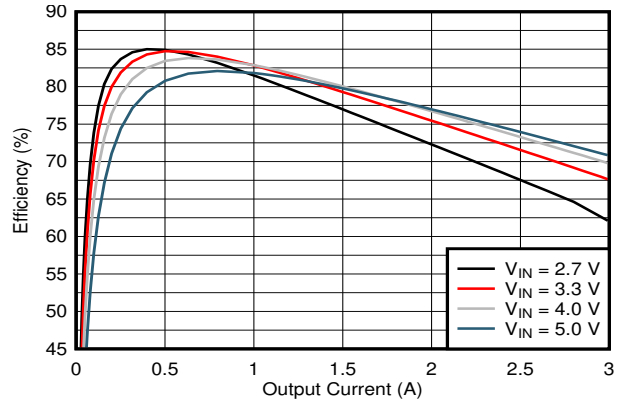
### 9.2.3 Application Curves

All plots have been taken with a nominal switching frequency of 2.25 MHz when set to PWM mode, unless otherwise noted. The BOM is according to 表 7-1.

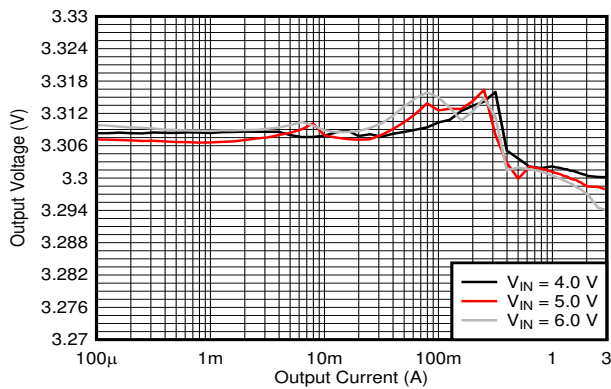




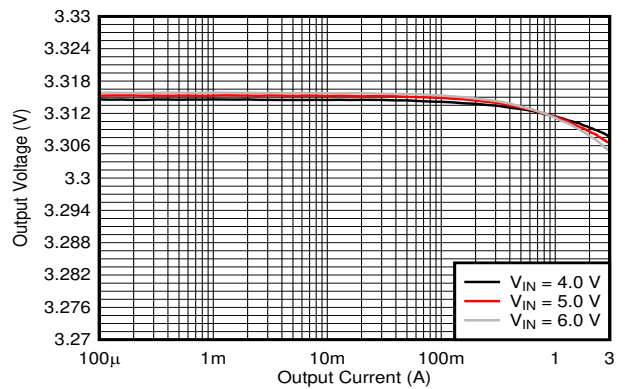
**9-8. Efficiency Versus Output Current**



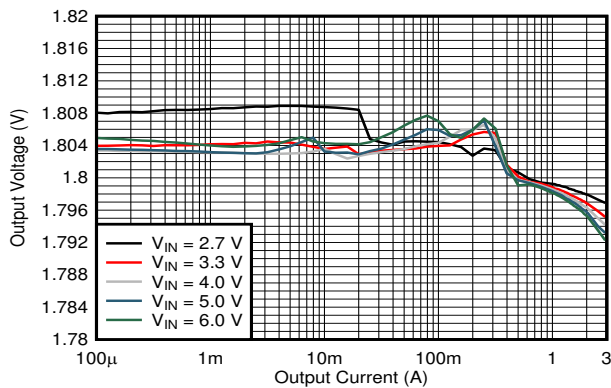
**9-9. Efficiency Versus Output Current**



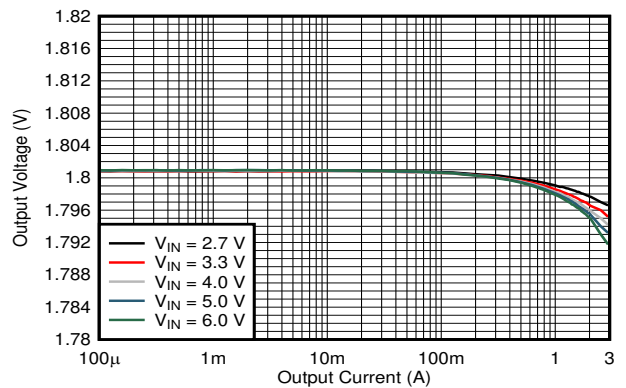
**9-10. Output Voltage Versus Output Current**



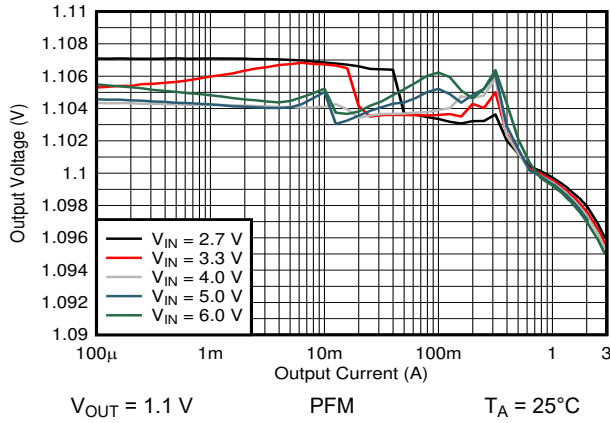
**9-11. Output Voltage Versus Output Current**



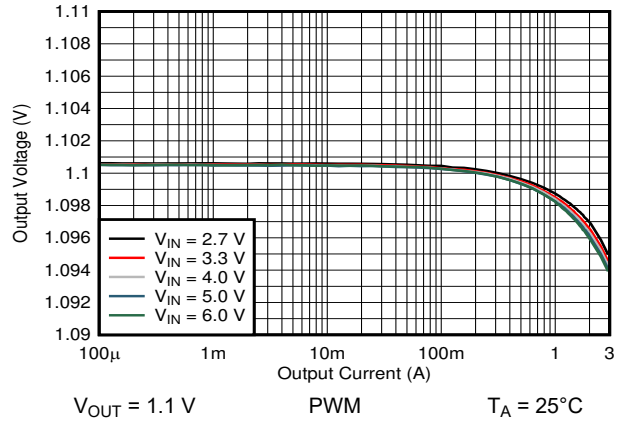
**9-12. Output Voltage Versus Output Current**



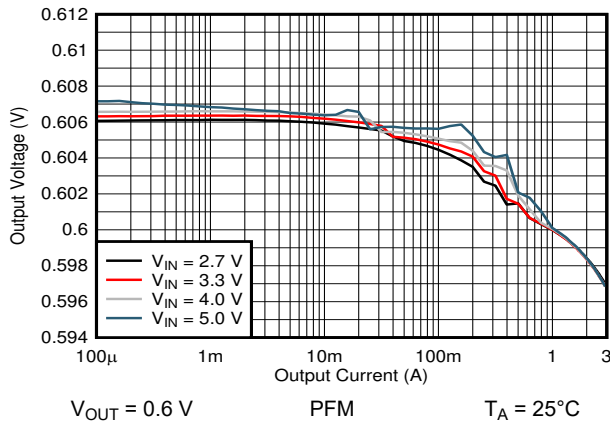
**9-13. Output Voltage Versus Output Current**



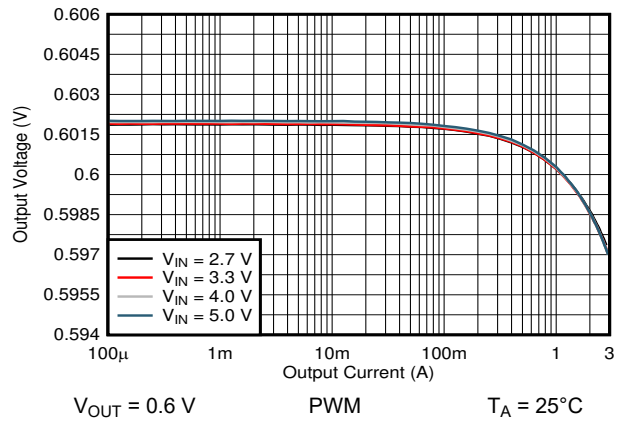
**9-14. Output Voltage Versus Output Current**



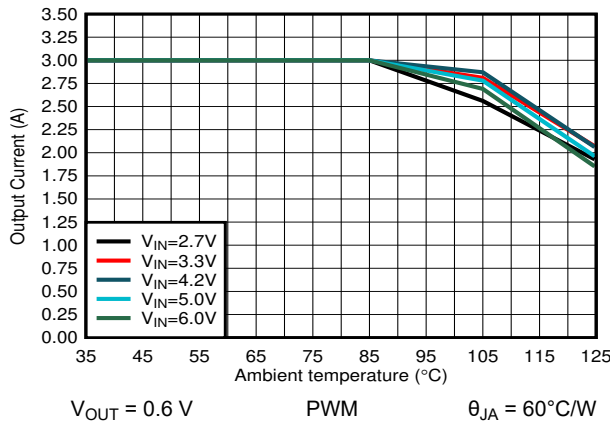
**9-15. Output Voltage Versus Output Current**



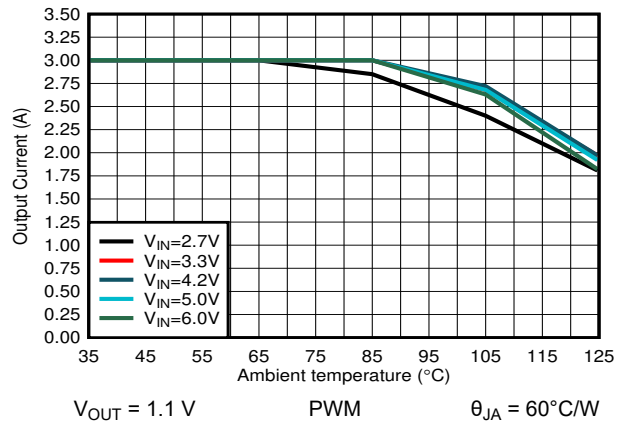
**9-16. Output Voltage Versus Output Current**



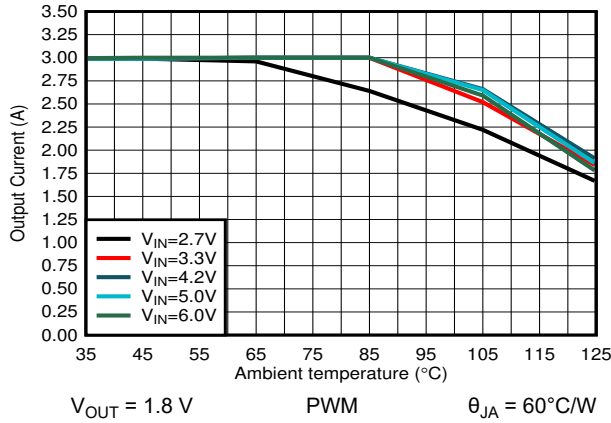
**9-17. Output Voltage Versus Output Current**



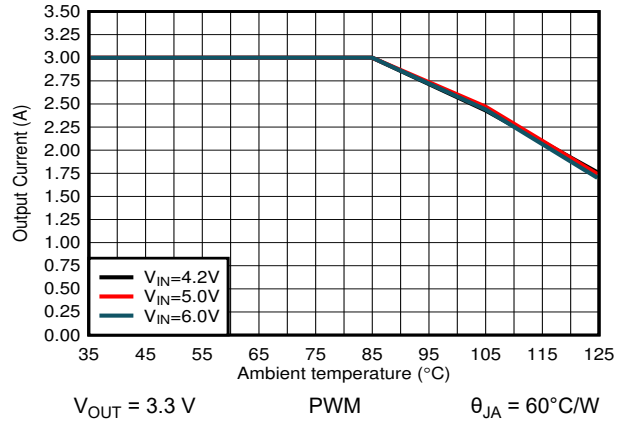
**9-18. Output Current Versus Ambient Temperature**



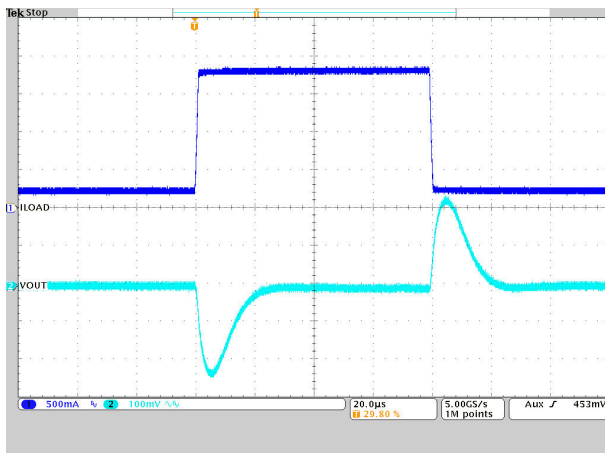
**9-19. Output Current Versus Ambient Temperature**



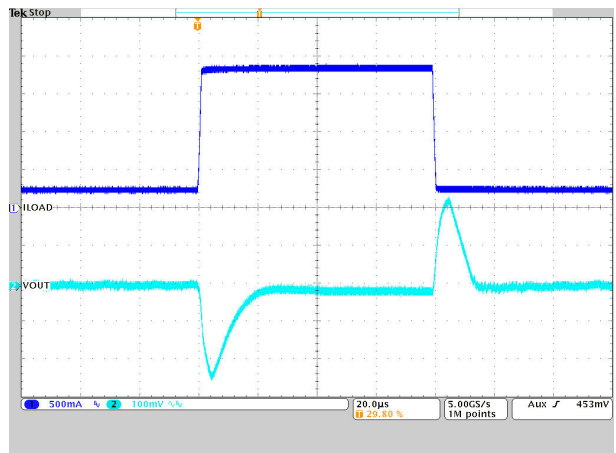
**9-20. Output Current Versus Ambient Temperature**



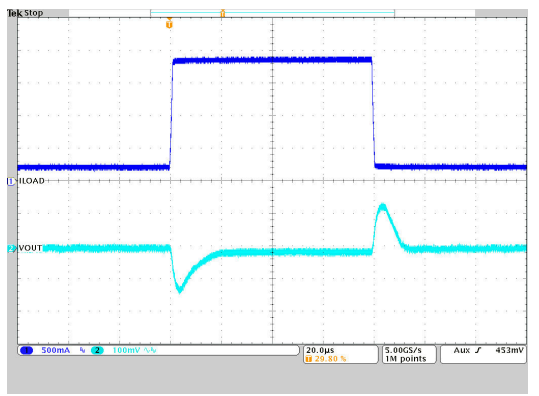
**9-21. Output Current Versus Ambient Temperature**



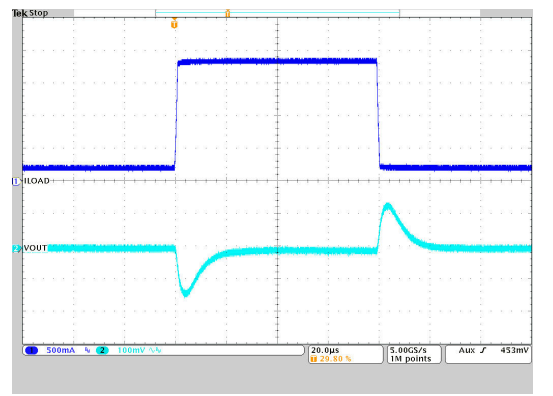
**9-22. Load Transient Response**



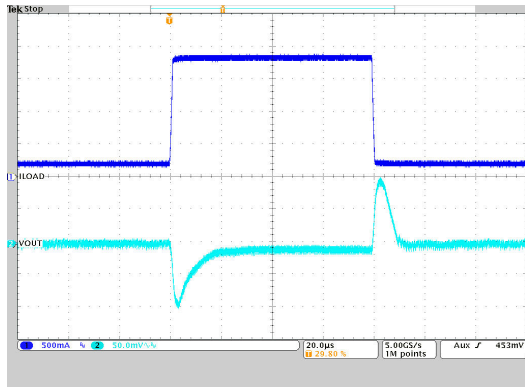
**9-23. Load Transient Response**



**9-24. Load Transient Response**

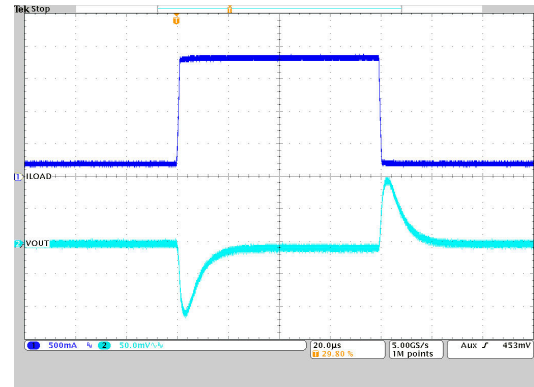


**9-25. Load Transient Response**



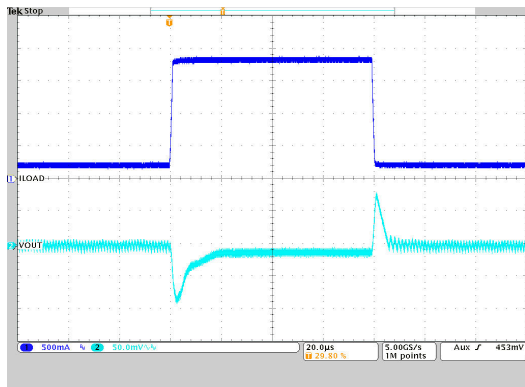
$V_{OUT} = 1.2\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5.0\text{ V}$        $I_{OUT} = 0.2\text{ A to } 1.8\text{ A to } 0.2\text{ A}$

**9-26. Load Transient Response**



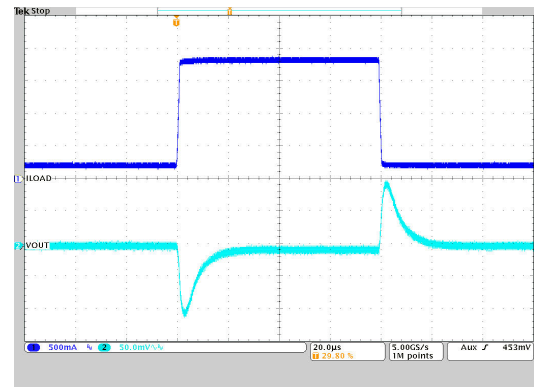
$V_{OUT} = 1.2\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5.0\text{ V}$        $I_{OUT} = 0.2\text{ A to } 1.8\text{ A to } 0.2\text{ A}$

**9-27. Load Transient Response**



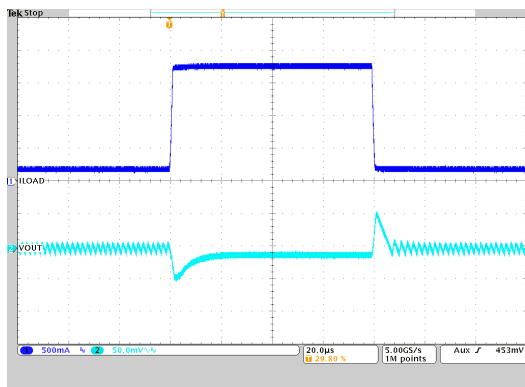
$V_{OUT} = 1.0\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5.0\text{ V}$        $I_{OUT} = 0.2\text{ A to } 1.8\text{ A to } 0.2\text{ A}$

**9-28. Load Transient Response**



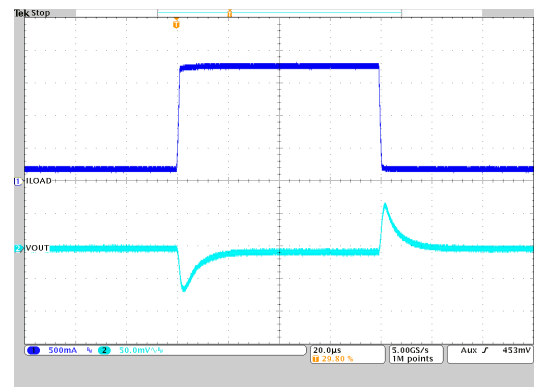
$V_{OUT} = 1.0\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5.0\text{ V}$        $I_{OUT} = 0.2\text{ A to } 1.8\text{ A to } 0.2\text{ A}$

**9-29. Load Transient Response**



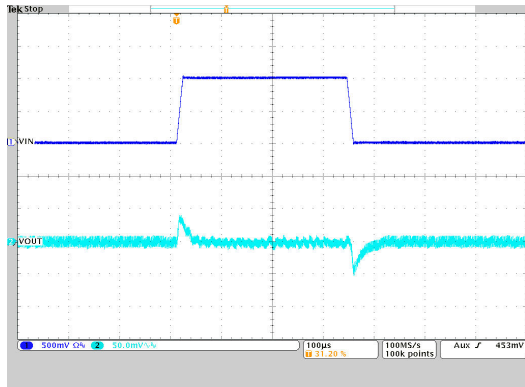
$V_{OUT} = 0.6\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 3.3\text{ V}$        $I_{OUT} = 0.2\text{ A to } 1.8\text{ A to } 0.2\text{ A}$

**9-30. Load Transient Response**



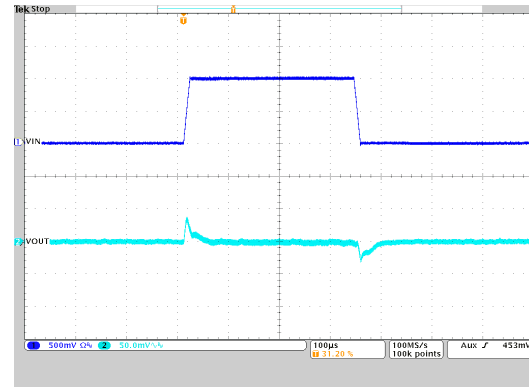
$V_{OUT} = 0.6\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 3.3\text{ V}$        $I_{OUT} = 0.2\text{ A to } 1.8\text{ A to } 0.2\text{ A}$

**9-31. Load Transient Response**



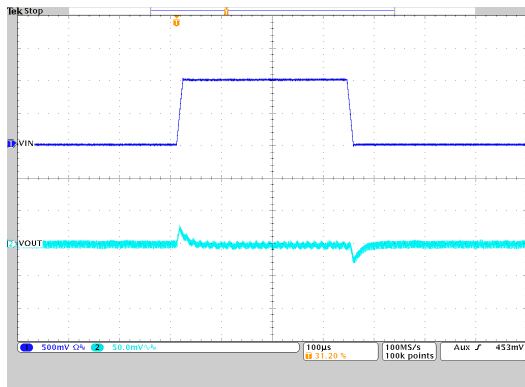
$V_{OUT} = 3.3\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 0.2\text{ A}$        $V_{IN} = 4.5\text{ V to } 5.5\text{ V to } 4.5\text{ V}$

**図 9-32. Line Transient Response**



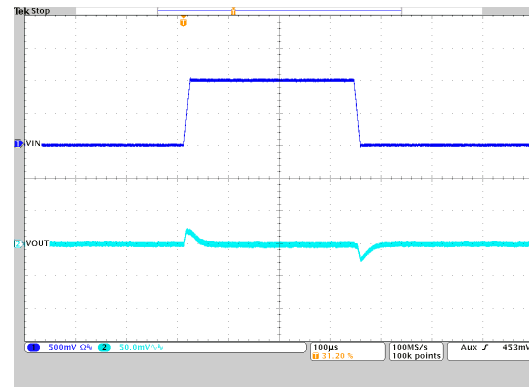
$V_{OUT} = 3.3\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 2\text{ A}$        $V_{IN} = 4.5\text{ V to } 5.5\text{ V to } 4.5\text{ V}$

**図 9-33. Line Transient Response**



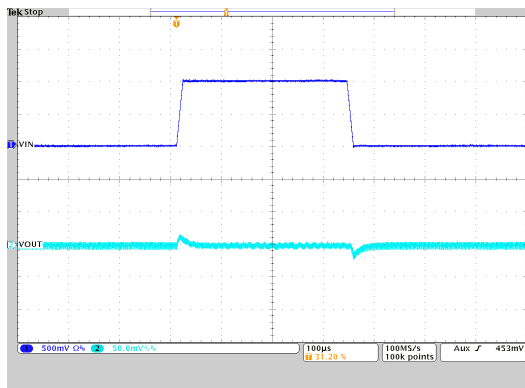
$V_{OUT} = 1.8\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 0.2\text{ A}$        $V_{IN} = 4.5\text{ V to } 5.5\text{ V to } 4.5\text{ V}$

**図 9-34. Line Transient Response**



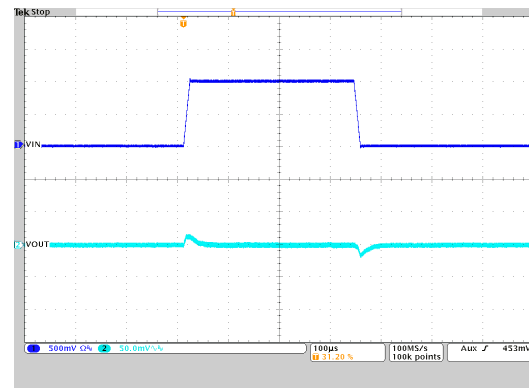
$V_{OUT} = 1.8\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 2\text{ A}$        $V_{IN} = 4.5\text{ V to } 5.5\text{ V to } 4.5\text{ V}$

**図 9-35. Line Transient Response**



$V_{OUT} = 1.2\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 0.2\text{ A}$        $V_{IN} = 4.5\text{ V to } 5.5\text{ V to } 4.5\text{ V}$

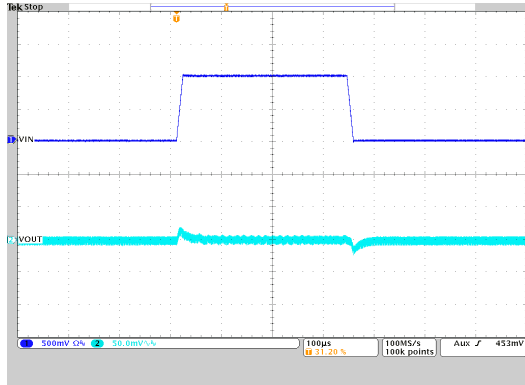
**図 9-36. Line Transient Response**



$V_{OUT} = 1.2\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 2\text{ A}$        $V_{IN} = 4.5\text{ V to } 5.5\text{ V to } 4.5\text{ V}$

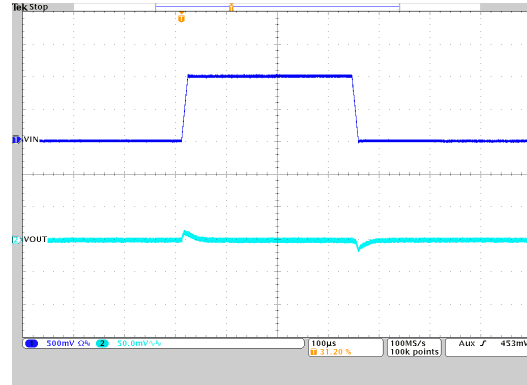
**図 9-37. Line Transient Response**





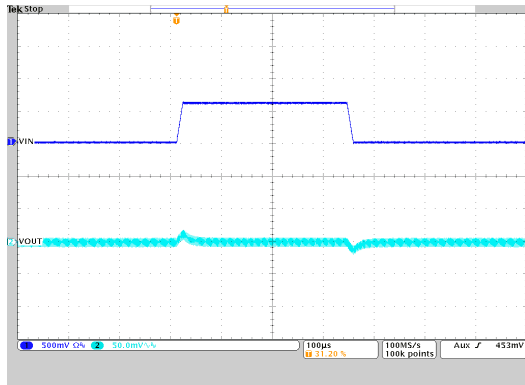
$V_{OUT} = 1.0\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 0.2\text{ A}$        $V_{IN} = 4.5\text{ V to } 5.5\text{ V to } 4.5\text{ V}$

**9-38. Line Transient Response**



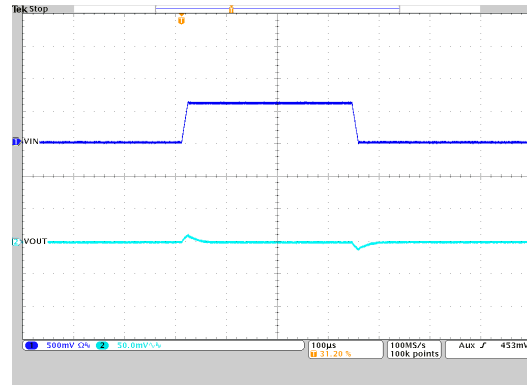
$V_{OUT} = 1.0\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 2\text{ A}$        $V_{IN} = 4.5\text{ V to } 5.5\text{ V to } 4.5\text{ V}$

**9-39. Line Transient Response**



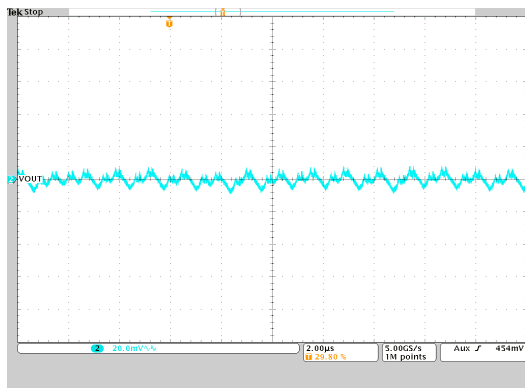
$V_{OUT} = 0.6\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 0.2\text{ A}$        $V_{IN} = 3.0\text{ V to } 3.6\text{ V to } 3.0\text{ V}$

**9-40. Line Transient Response**



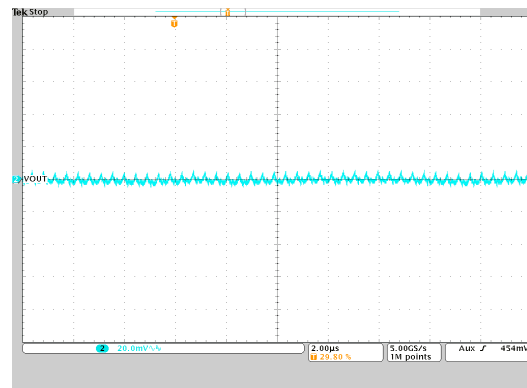
$V_{OUT} = 0.6\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $I_{OUT} = 2\text{ A}$        $V_{IN} = 3.0\text{ V to } 3.6\text{ V to } 3.0\text{ V}$

**9-41. Line Transient Response**



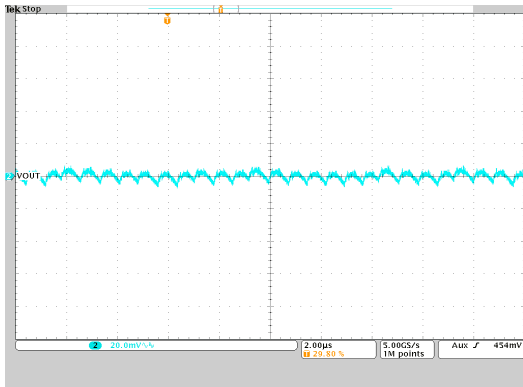
$V_{OUT} = 3.3\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$        $I_{OUT} = 0.2\text{ A}$

**9-42. Output Voltage Ripple**



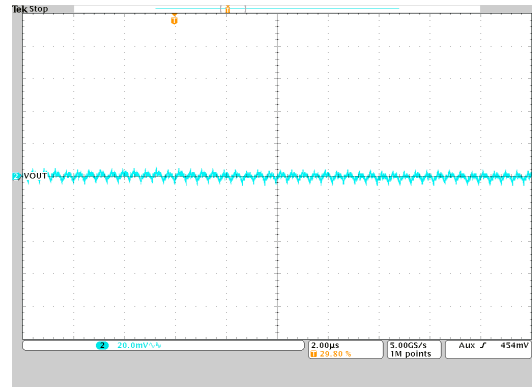
$V_{OUT} = 3.3\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$        $I_{OUT} = 2\text{ A}$

**9-43. Output Voltage Ripple**



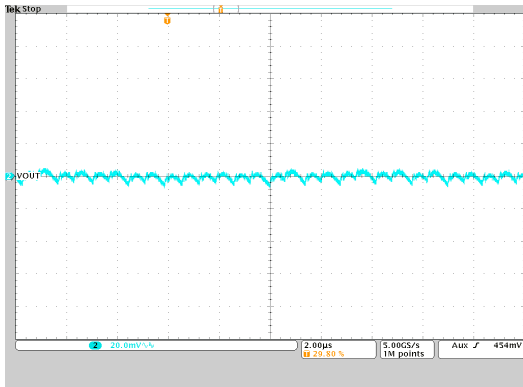
$V_{OUT} = 1.8\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$                        $I_{OUT} = 0.2\text{ A}$

**図 9-44. Output Voltage Ripple**



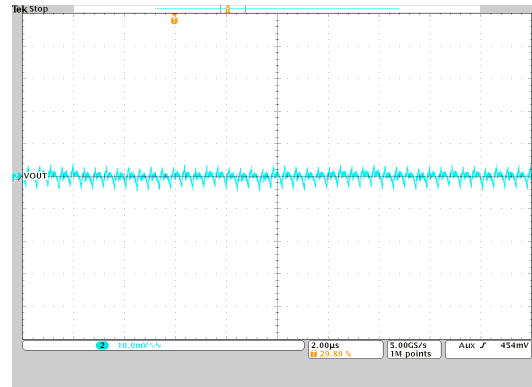
$V_{OUT} = 1.8\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$                        $I_{OUT} = 2\text{ A}$

**図 9-45. Output Voltage Ripple**



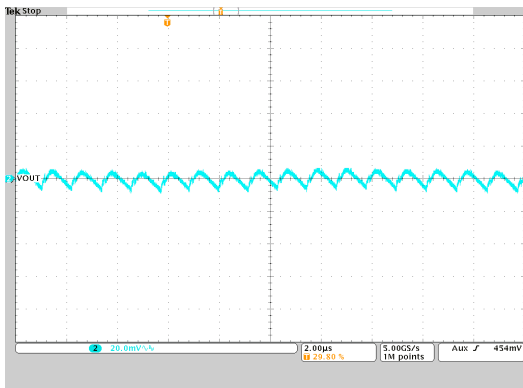
$V_{OUT} = 1.2\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$                        $I_{OUT} = 0.2\text{ A}$

**図 9-46. Output Voltage Ripple**



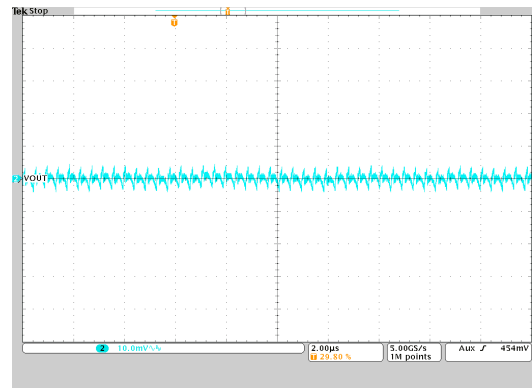
$V_{OUT} = 1.2\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$                        $I_{OUT} = 2\text{ A}$

**図 9-47. Output Voltage Ripple**



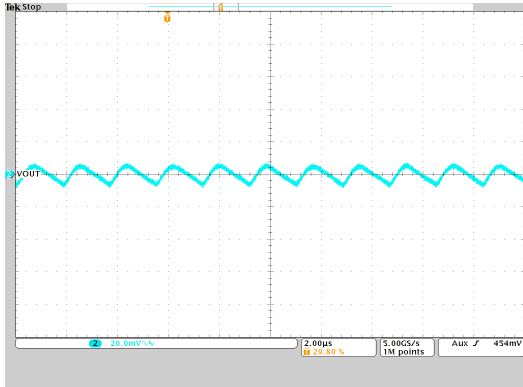
$V_{OUT} = 1.0\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$                        $I_{OUT} = 0.2\text{ A}$

**図 9-48. Output Voltage Ripple**



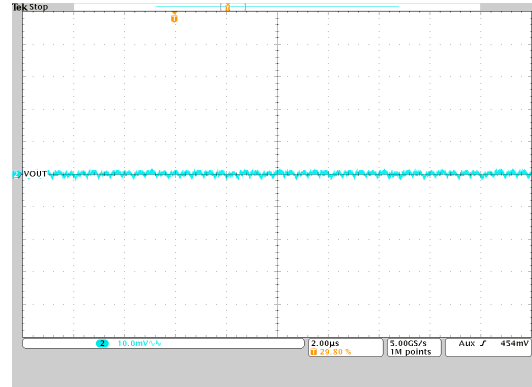
$V_{OUT} = 1.0\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$                        $I_{OUT} = 2\text{ A}$

**図 9-49. Output Voltage Ripple**



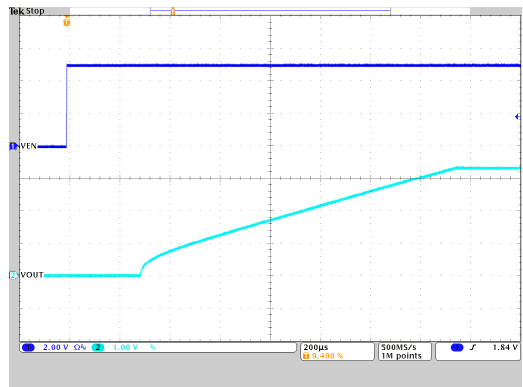
$V_{OUT} = 0.6\text{ V}$       PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 3.3\text{ V}$        $I_{OUT} = 0.2\text{ A}$

**9-50. Output Voltage Ripple**



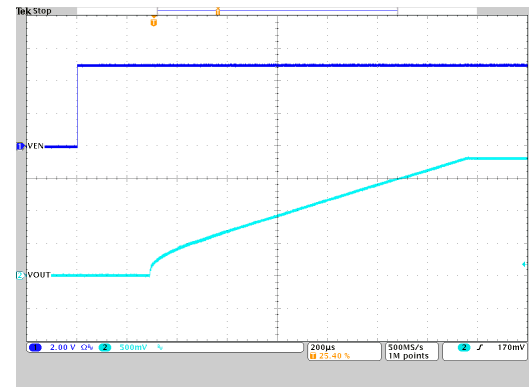
$V_{OUT} = 0.6\text{ V}$       PWM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 3.3\text{ V}$        $I_{OUT} = 2\text{ A}$

**9-51. Output Voltage Ripple**



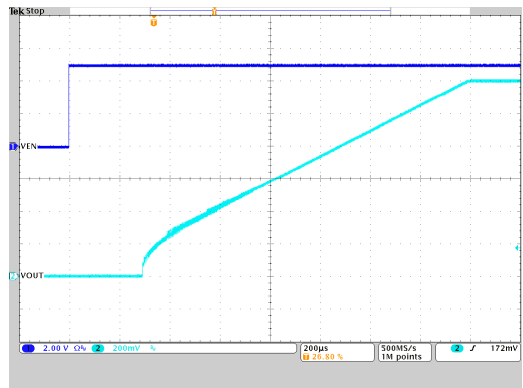
$V_{OUT} = 3.3\text{ V}$       PWM or PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$        $I_{OUT} = 2\text{ A}$

**9-52. Start-Up Timing**



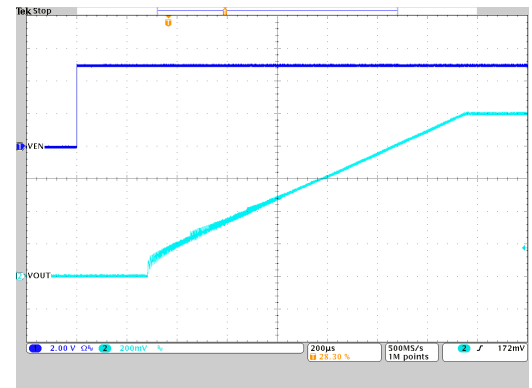
$V_{OUT} = 1.8\text{ V}$       PWM or PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$        $I_{OUT} = 2\text{ A}$

**9-53. Start-Up Timing**



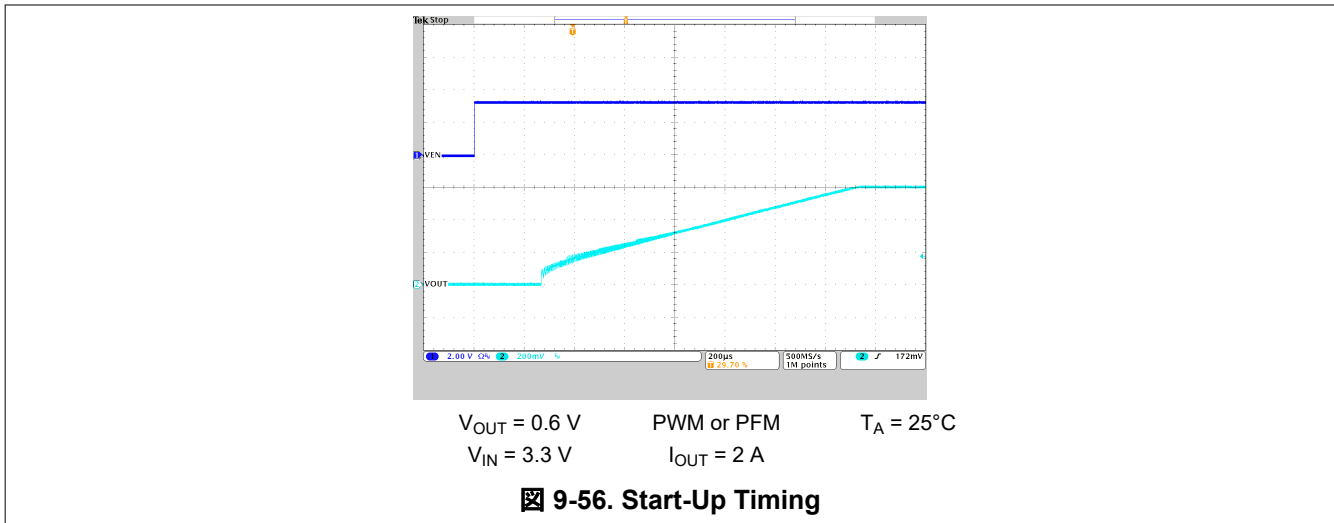
$V_{OUT} = 1.2\text{ V}$       PWM or PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$        $I_{OUT} = 2\text{ A}$

**9-54. Start-Up Timing**



$V_{OUT} = 1.0\text{ V}$       PWM or PFM       $T_A = 25^\circ\text{C}$   
 $V_{IN} = 5\text{ V}$        $I_{OUT} = 2\text{ A}$

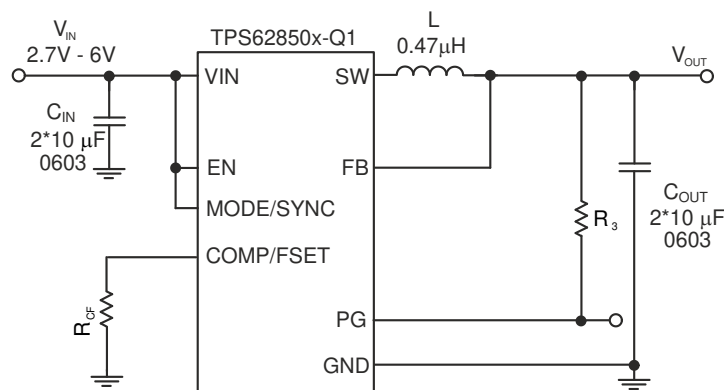
**9-55. Start-Up Timing**



## 9.3 System Examples

### 9.3.1 Fixed Output Voltage Versions

Versions with an internally fixed output voltage allow you to remove the external feedback voltage divider. This not only allows you to reduce the total solution size but also provides higher accuracy as there is no additional error caused by the external resistor divider. The FB pin must be tied to the output voltage directly as shown in 9-57. The application runs with an internally defined switching frequency of 2.25 MHz by connecting COMP/FSET to GND.



**9-57. Schematic for Fixed Output Voltage Versions**

### 9.3.2 Synchronizing to an External Clock

The TPS62850x-Q1 can be externally synchronized by applying an external clock on the MODE/SYNC pin. There is no need for any additional circuitry as long as the input signal meets the requirements given in the electrical specifications. The clock can be applied / removed during operation, allowing you to switch from an externally defined fixed frequency to power-save mode or to internal fixed frequency operation.

The value of the  $R_{CF}$  resistor must be chosen such that the internally defined frequency and the externally applied frequency are close to each other. This ensures a smooth transition from internal to external frequency and vice versa.

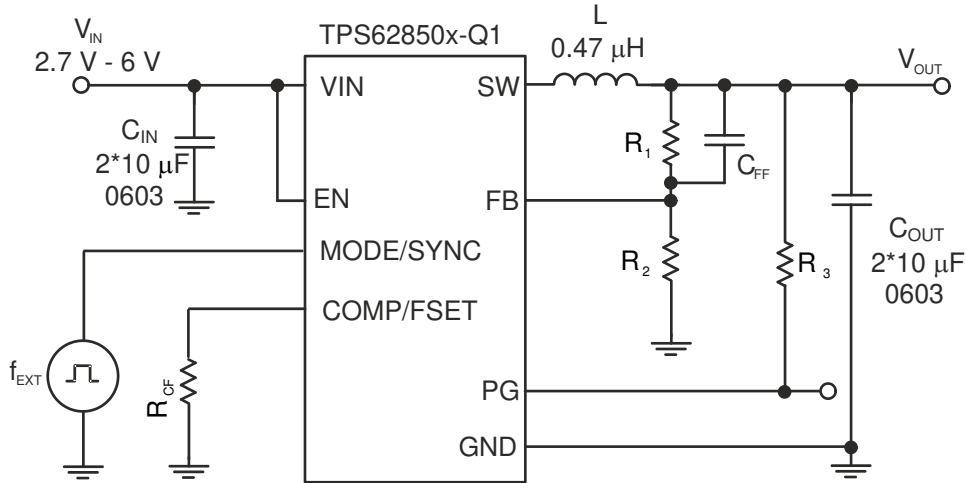


図 9-58. Schematic using External Synchronization

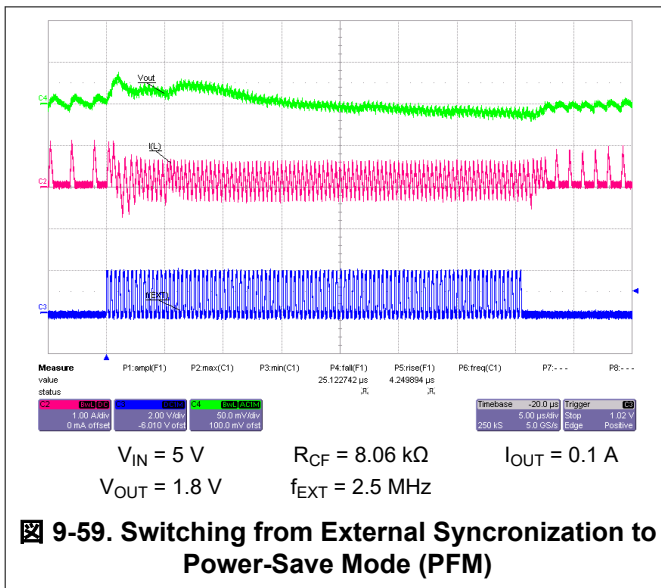


図 9-59. Switching from External Synchronization to Power-Save Mode (PFM)

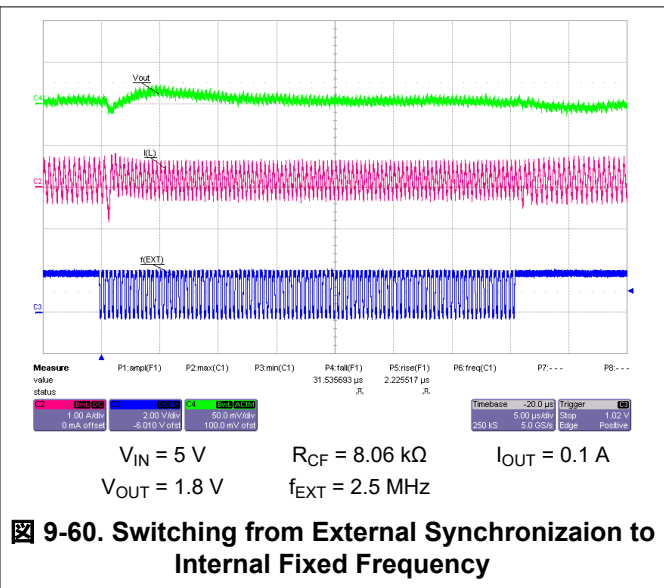


図 9-60. Switching from External Synchronization to Internal Fixed Frequency

## 9.4 Power Supply Recommendations

The TPS62850x-Q1 device family does not have special requirements for its input power supply. The output current of the input power supply must be rated according to the supply voltage, output voltage, and output current of the TPS62850x-Q1.

## 9.5 Layout

### 9.5.1 Layout Guidelines

A proper layout is critical for the operation of a switched mode power supply, even more at high switching frequencies. Therefore, the PCB layout of the TPS62850x-Q1 demands careful attention to ensure operation and to get the performance specified. A poor layout can lead to issues like poor regulation (both in [セクション 9.5.2](#) and load), stability and accuracy weaknesses, increased EMI radiation, and noise sensitivity.

See for the recommended layout of the TPS62850x-Q1, which is designed for common external ground connections. The input capacitor must be placed as close as possible between the VIN and GND pin.

Provide low inductive and resistive paths for loops with high di/dt. Therefore, paths conducting the switched load current must be as short and wide as possible. Provide low capacitive paths (with respect to all other nodes) for

wires with high  $dv/dt$ . Therefore, the input and output capacitance must be placed as close as possible to the IC pins and parallel wiring over long distances and narrow traces must be avoided. Loops which conduct an alternating current must outline an area as small as possible, as this area is proportional to the energy radiated.

Sensitive nodes like FB must be connected with short wires and not nearby high  $dv/dt$  signals (for example, SW). As they carry information about the output voltage, they must be connected as close as possible to the actual output voltage (at the output capacitor). The FB resistors,  $R_1$  and  $R_2$ , must be kept close to the IC and be connected directly to the pin and the system ground plane.

The package uses the pins for power dissipation. Thermal vias on the VIN and GND pins help to spread the heat into the pcb.

The recommended layout is implemented on the EVM and shown in the [TPS628502EVM-092 Evaluation Module User's Guide](#).

### 9.5.2 Layout Example

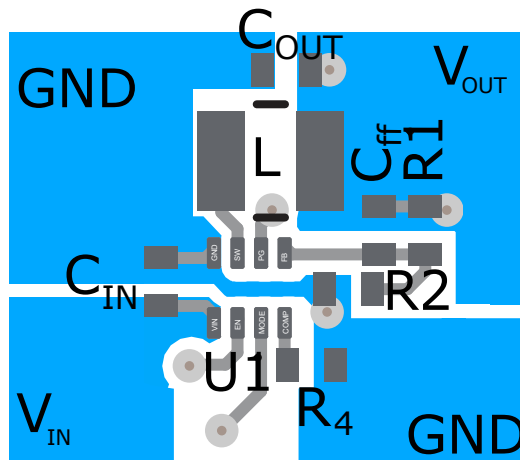


図 9-61. Example Layout

## 10 Device and Documentation Support

### 10.1 Device Support

#### 10.1.1 サード・パーティ製品に関する免責事項

サード・パーティ製品またはサービスに関するテキサス・インスツルメンツの出版物は、単独またはテキサス・インスツルメンツの製品、サービスと一緒に提供される場合に関係なく、サード・パーティ製品またはサービスの適合性に関する是認、サード・パーティ製品またはサービスの是認の表明を意味するものではありません。

#### 10.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[www.tij.co.jp](http://www.tij.co.jp) のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

#### 10.3 サポート・リソース

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#### 10.5 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

#### 10.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

## 11 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision J (November 2023) to Revision K (June 2024)	Page
• Added TPS628501B0QDRLRQ1 and TPS62850120QDRLRQ1 .....	3
• Updated the third row (33 kΩ .. 15 kΩ) in 表 8-1 to show best transient performance instead of lowest output capacitance.....	12

Changes from Revision I (July 2023) to Revision J (November 2023)	Page
• Added TPS62850120QDRLRQ1 and TPS6285020AQDRLRQ1 .....	3

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**Changes from Revision H (March 2023) to Revision I (July 2023)**

**Page**

- Removed the preview note from TPS6285011HQDRLRQ1, TPS62850140QDYCRQ1 and TPS62850240QDYCRQ1..... **3**
-



## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS6285010MQDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	10MQ	<a href="#">Samples</a>
TPS6285010MQDYCRQ1	ACTIVE	SOT-5X3	DYC	8	4000	RoHS & Green	Call TI   SN	Level-2-260C-1 YEAR	-40 to 125	10MQ	<a href="#">Samples</a>
TPS6285011HQDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-2-260C-1 YEAR	-40 to 125	11HQ	<a href="#">Samples</a>
TPS62850120QDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	120Q	<a href="#">Samples</a>
TPS62850140QDYCRQ1	ACTIVE	SOT-5X3	DYC	8	4000	RoHS & Green	Call TI   SN	Level-2-260C-1 YEAR	-40 to 125	140Q	<a href="#">Samples</a>
TPS6285018AQDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	18AQ	<a href="#">Samples</a>
TPS628501B0QDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	10BQ	<a href="#">Samples</a>
TPS628501QDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	100Q	<a href="#">Samples</a>
TPS6285020AQDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	20AQ	<a href="#">Samples</a>
TPS6285020MQDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	20MQ	<a href="#">Samples</a>
TPS6285021HQDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 150	21HQ	<a href="#">Samples</a>
TPS62850220QDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	220Q	<a href="#">Samples</a>
TPS62850240QDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 150	240Q	<a href="#">Samples</a>
TPS62850240QDYCRQ1	ACTIVE	SOT-5X3	DYC	8	4000	RoHS & Green	Call TI   SN	Level-2-260C-1 YEAR	-40 to 125	240Q	<a href="#">Samples</a>
TPS628502QDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	200Q	<a href="#">Samples</a>
TPS628503QDRLRQ1	ACTIVE	SOT-5X3	DRL	8	4000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	300Q	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of  $\leq 1000$ ppm threshold. Antimony trioxide based flame retardants must also meet the  $\leq 1000$ ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**OTHER QUALIFIED VERSIONS OF TPS628501-Q1, TPS628502-Q1, TPS628503-Q1 :**

- Catalog : [TPS628501](#), [TPS628502](#), [TPS628503](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

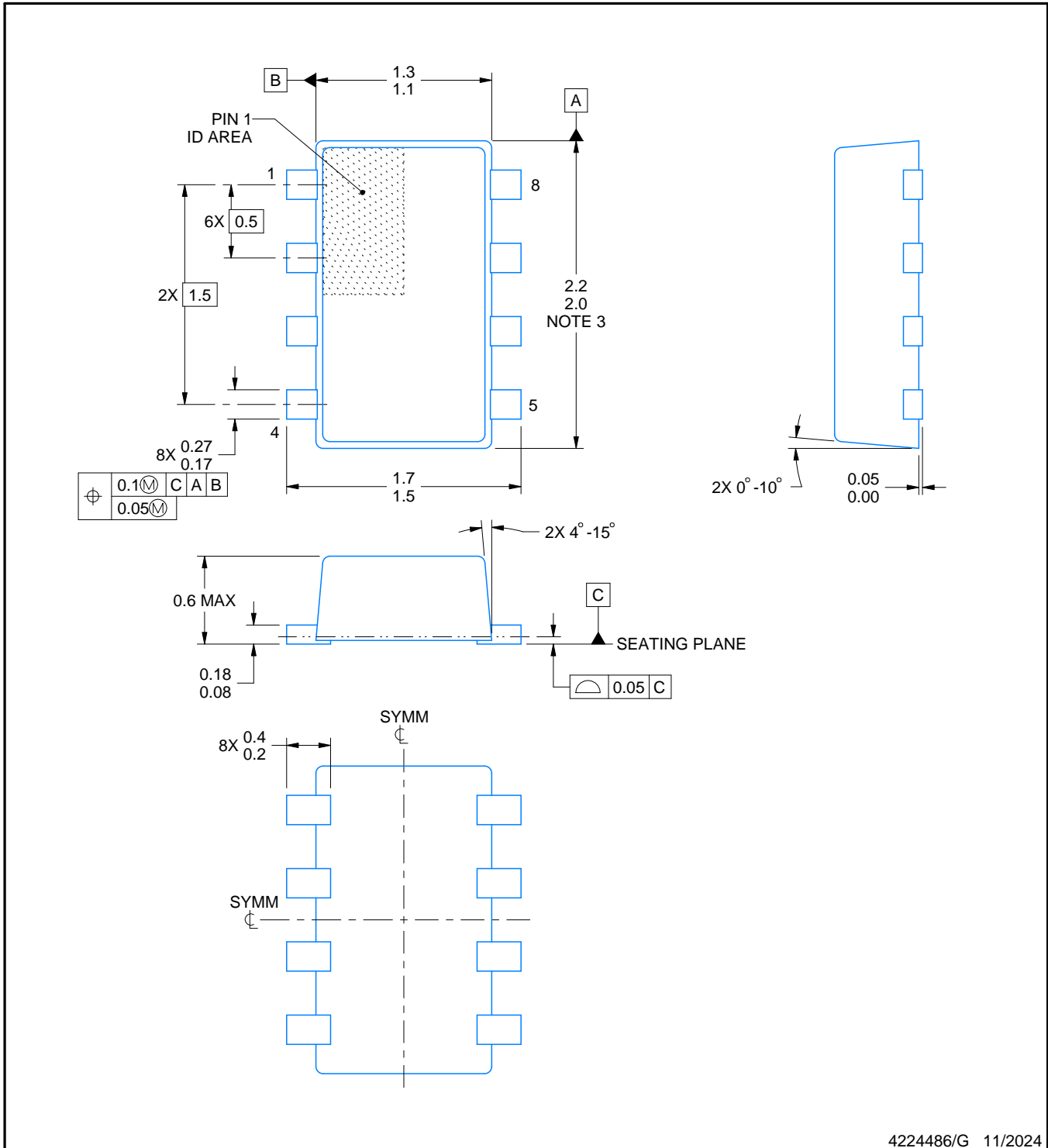

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS6285010MQDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS6285010MQDYCRQ1	SOT-5X3	DYC	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS6285011HQDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS62850120QDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS62850140QDYCRQ1	SOT-5X3	DYC	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS6285018AQDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS628501B0QDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS628501QDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS6285020AQDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS6285020MQDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS6285021HQDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS62850220QDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS62850240QDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS62850240QDYCRQ1	SOT-5X3	DYC	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS628502QDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3
TPS628503QDRLRQ1	SOT-5X3	DRL	8	4000	180.0	8.4	2.75	1.9	0.8	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS6285010MQDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS6285010MQDYCRQ1	SOT-5X3	DYC	8	4000	210.0	185.0	35.0
TPS6285011HQDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS62850120QDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS62850140QDYCRQ1	SOT-5X3	DYC	8	4000	210.0	185.0	35.0
TPS6285018AQDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS628501B0QDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS628501QDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS6285020AQDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS6285020MQDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS6285021HQDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS62850220QDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS62850240QDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS62850240QDYCRQ1	SOT-5X3	DYC	8	4000	210.0	185.0	35.0
TPS628502QDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0
TPS628503QDRLRQ1	SOT-5X3	DRL	8	4000	210.0	185.0	35.0



NOTES:

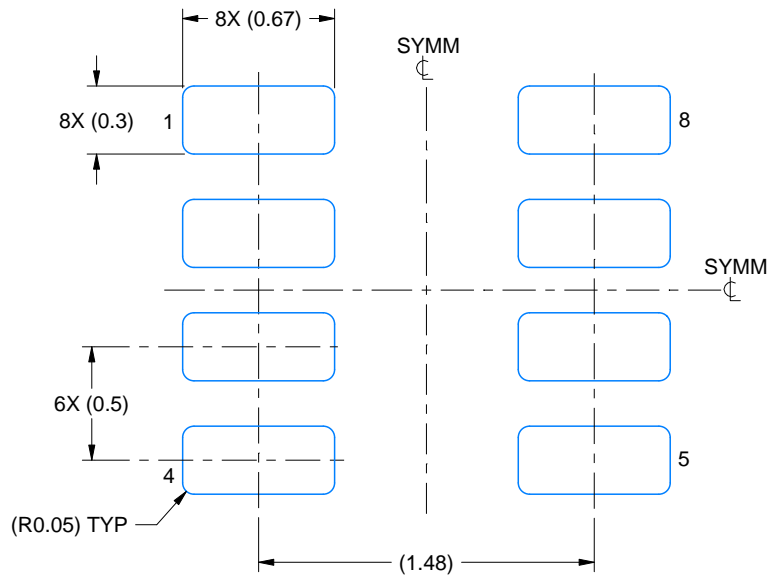
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC Registration MO-293, Variation UDAD

# EXAMPLE BOARD LAYOUT

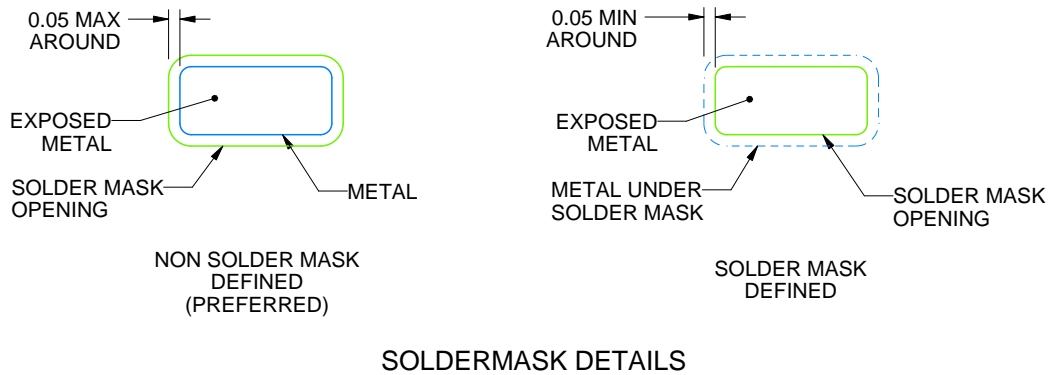
DRL0008A

SOT-5X3 - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:30X



SOLDERMASK DETAILS

4224486/G 11/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

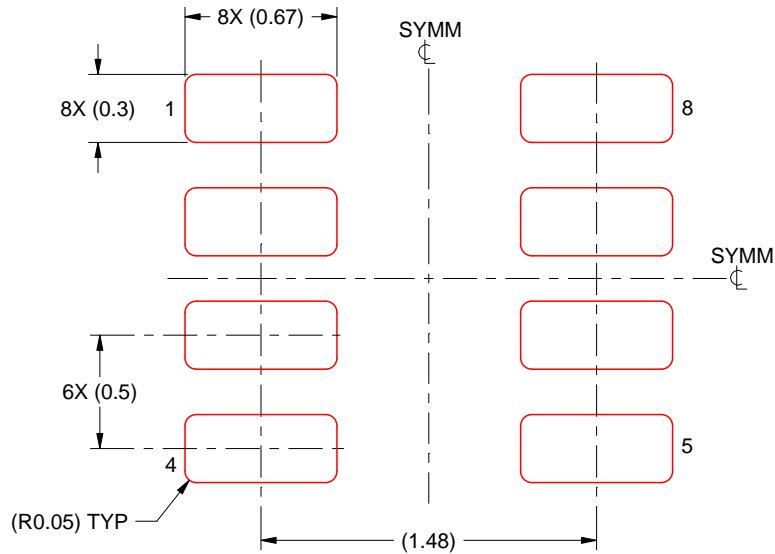


# EXAMPLE STENCIL DESIGN

DRL0008A

SOT-5X3 - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:30X

4224486/G 11/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

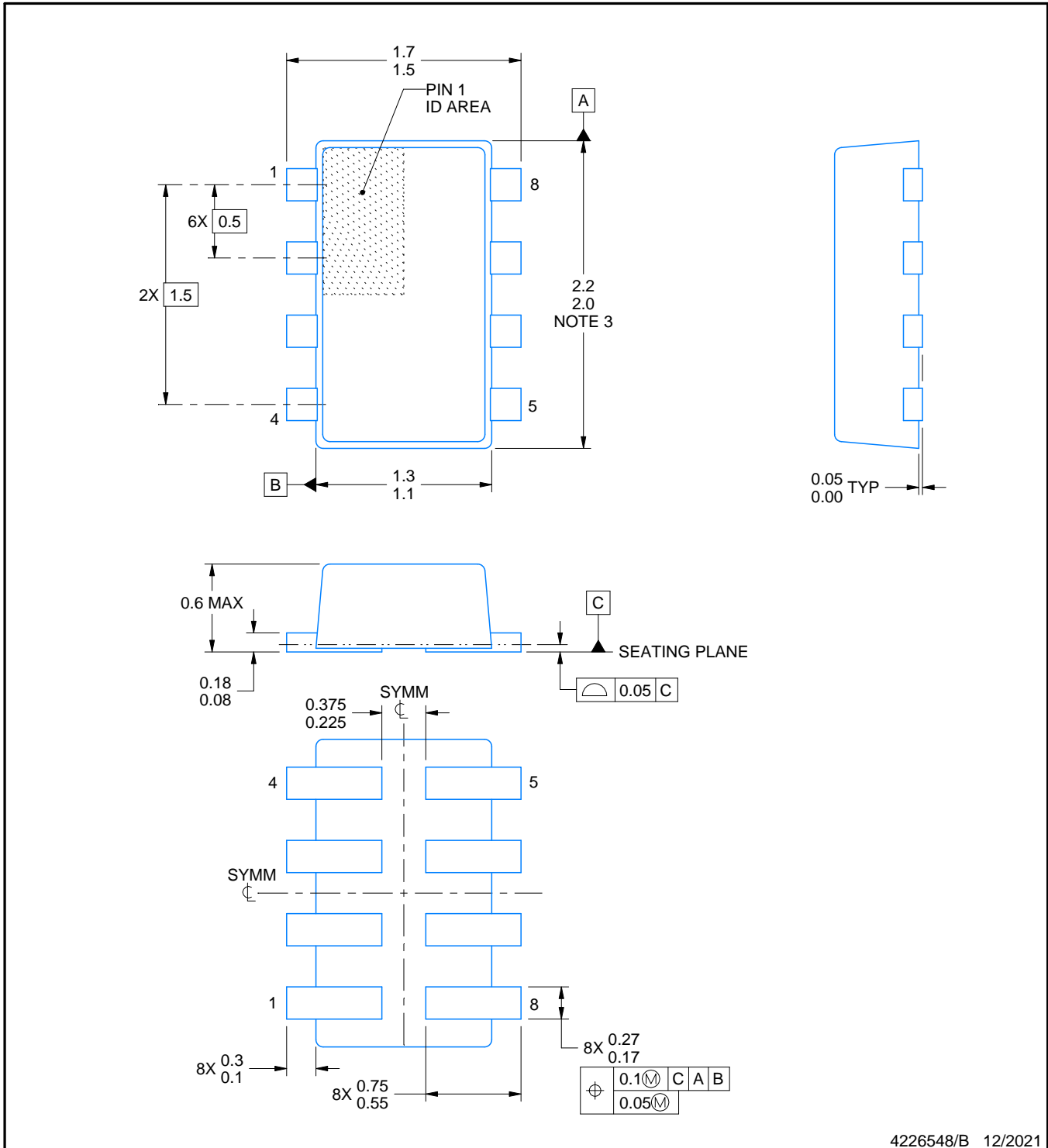
# DYC0008A



# PACKAGE OUTLINE

## SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



4226548/B 12/2021

### NOTES:

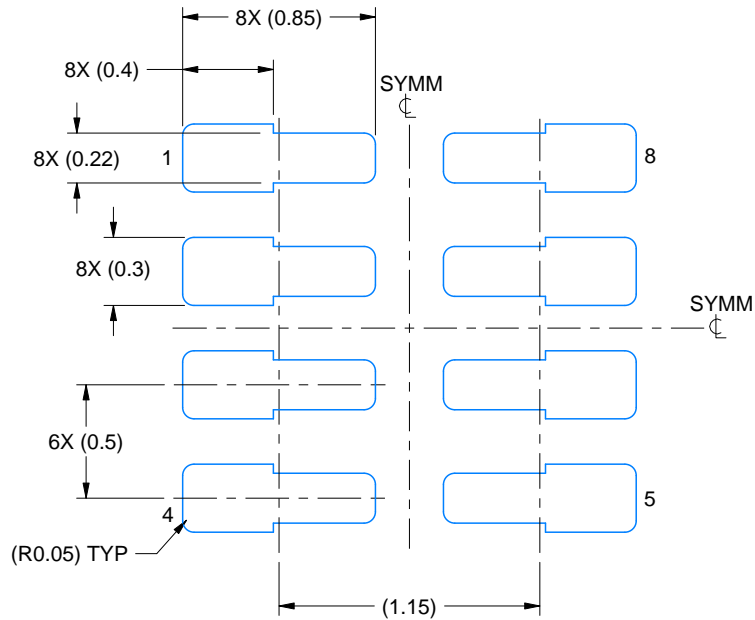
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

# EXAMPLE BOARD LAYOUT

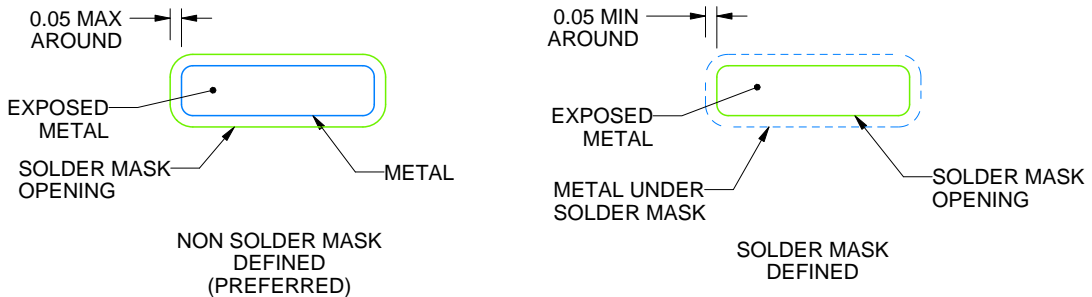
DYC0008A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:30X



SOLDERMASK DETAILS

4226548/B 12/2021

NOTES: (continued)

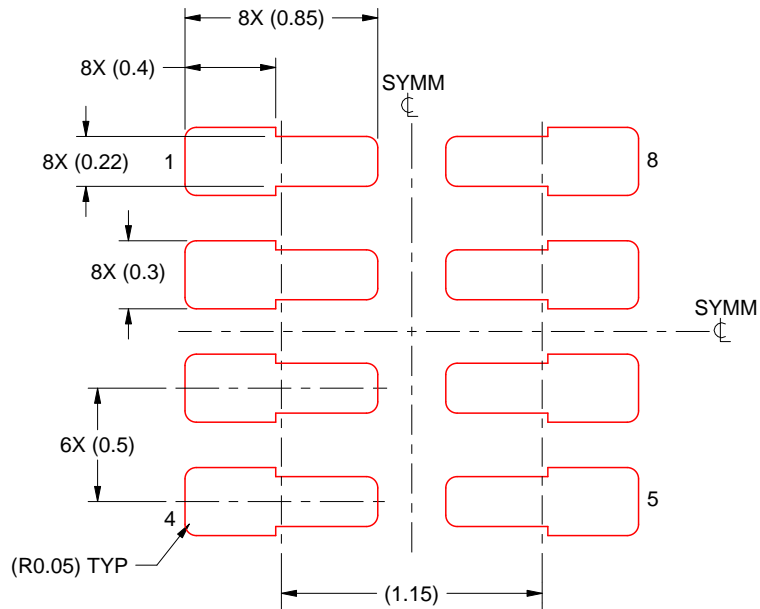
4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
6. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

# EXAMPLE STENCIL DESIGN

DYC0008A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:30X

4226548/B 12/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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